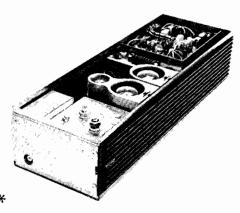
MASTR Progress Line

25-50 MC, 100-WATT TRANSMITTER MODELS 4ET55A10-27



SPECIFICATIONS

FCC Filing Designation:

Power Output:

Frequency Range:

Crystal Multiplication Factor:

Frequency Stability:

Spurious & Harmonic Radiation:

Modulation:

Audio Frequency Characteristics:

Distortion:

Deviation Symmetry:

Tubes & Transistors:

Maximum Frequency Spacing:

Duty Cycle:

Mobile-

Station-

ET-55-A

25-50 MC

100 watts minimum

 $\pm .0005\%$ (-30°C to +60°C)

At least 85 db below rated power output

Adjustable from 0 to ±5 KC swing with

instantaneous modulation limiting

Within +1 db to -3 db of a 6 db/octave pre-emphasis from 300 to 3000 cps per EIA

standards.

Post limiter filter per FCC and EIA.

Less than 5%

0.5 KC maximum

100-Watt Transmitter with no Options:

3 tubes

6 transistors

4 diodes

0.4 %

20% transmit (one minute transmit, four minutes off)

Continuous

*These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Certified and Guaranteed Specification Sheet for the complete specifications.

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— WARNING —

No one should be permitted to handle any portion of the equipment that is supplied with high voltage; or to connect any external apparatus to the units while the units are supplied with power. KEEP AWAY FROM LIVE CIRCUITS.

DESCRIPTION

The MASTR Progress Line FM Transmitter, Type ET-55-A, is a crystal-controlled, phase-modulated transmitter designed for one-, two- or four-frequency operation within the 25-50 megacycle band. The transmitter consists of the following modules:

- Transistorized Exciter Board, with audio, oscillator modulator, amplifier and multiplier stages,
- Tubed multiplier and power amplifier stages,
- Optional transistorized Channel Guard Board.

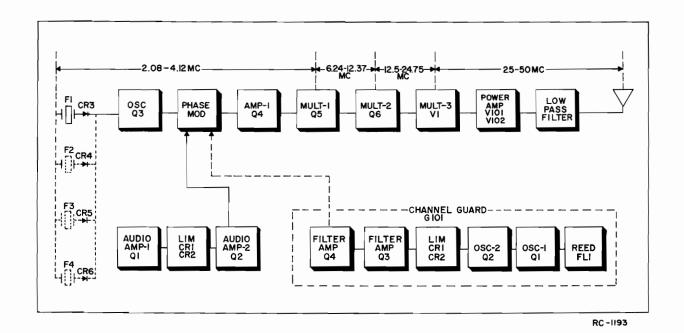


Figure 1 - Transmitter Block Diagram

All input leads to the transmitter are individually filtered by the 20-pin feed-through by-pass connector J101. The output passes through a four-section, low-pass filter that features good shielding between sections and Teflon® capacitors for fail-free operation with an open or shorted antenna.

CIRCUIT ANALYSIS

Six silicon transistors and only three tubes are used in the transmitter to provide a minimum power output of 100 watts. The frequency of the crystals used ranges from 2 to 4.2 megacycles, and the crystal frequency is multiplied 12 times.

A centralized metering jack (J102) is provided for use with General Electric Test Set 4EX3A10. The Test Set meters the multiplier, amplifier and PA stages as well as filament and regulated supply voltages. The metering jack also provides access to receiver audio, microphone and push-to-talk leads.

POWER INPUTS

The following supply voltages are connected from the power supply to the transmitter through the 20-pin by-pass connector J101:

Pin 3 - Filament Voltage

Pin 4 - +300 volts MULT B+

Pin 5 - +650 volts PA B+

Pin 8 - -45 volts bias

Pin 14 - +10 volts for Channel Guard option

Pin 15 - -20 volts for Exciter Board.

OSCILLATOR

A transistorized Colpitts oscillator (Q3) is used in the transmitter. The oscillator crystal is thermistor compensated at both ends of the temperature range to provide instant frequency compensation with a frequency stability of $\pm .0005\%$ without crystal ovens or warmers.

In single-frequency transmitters, a jumper (from H1 to H2) connects the F1 crystal keying lead to ground to forward bias diode CR3. Forward biasing the diode reduces its impedance, and the crystal frequency is applied to the base of oscillator Q3. Feedback for the oscillator is developed across C41/C42. The oscillator output is coupled directly to the phase modulator.

In multi-frequency transmitters, the single oscillator transistor is used, and up to three additional crystal circuits, identical to the Fl crystal circuit, can be added. The keying jumper is removed and the proper frequency is selected by switching the crystal keying lead to ground by means of a frequency selector switch on the Control Unit.

AUDIO AMPLIFIERS AND LIMITER

An audio signal from the microphone is coupled through Cl to the base of Class A audio amplifier Ql. The design of the microphone, in

conjunction with C2 and R3, produces a 6-db audio pre-emphasis. R48 and C74 provides RF de-coupling.

The amplified audio signal is RC-coupled to the diode limiters, CRl and CR2. These diodes operate in series and are normally in a forward conducting state. An audio signal of sufficient amplitude to cause limiting takes the diodes out of conduction, so that one diode conducts only on positive cycles and the other conducts only on negative cycles.

Following the limiter stage is a second Class A amplifier, Q2. The output of Q2 is coupled through MOD ADJUST potentiometer R14 to a combined post-limiter filter and de-emphasis network. This network consists of R17, R18, R19, C5, C8, C9 and C49. The output of the filter and de-emphasis network is applied directly to the phase modulator.

PHASE MODULATOR

The phase modulator is a varactor (voltage-variable capacitor) CV-1 in series with tuneable coil L1. This network appears as a series-resonant circuit to the RF output of the oscillator. An audio signal applied to the modulator varies the bias of CV-1, resulting in a phase modulated output. The output of the modulator is coupled through blocking capacitor C51 to the base of the first amplifier. For Channel Guard transmitters, a second modulator stage (L2 and CV-2) is cascaded with the first modulator. The output of the Channel Guard encoder is fed through CHANNEL GUARD MOD ADJUST R20 to the modulator stages.

AMPLIFIERS, 1ST AND 2ND MULTIPLIERS

The first amplifier (Q4) isolates the modulator from the loading effects of the first multiplier and provides amplification. The output is DC-coupled to the first multiplier. Metering resistor R41 permits the MULT-1 stage to be metered at centralized metering jack J102-10.

Following Q4 are two inductively coupled Class C, common-emitter multiplier stages (Q5 and Q6). Q5 is a tripler, with collector tank L3 tuned to three times the crystal frequency.

Q6 operates as a doubler stage, with collector tank Tl tuned to six times the crystal frequency. Resistor R43 is for metering the MULT-2 stage at J102-2.

THIRD MULTIPLIER

The output of the transistorized Exciter is coupled by a short length of RF cable to the grid tank (L9/L10/L11) of beam pentode V1. This stage operates as a doubler with the plate tank tuned to 12 times the crystal frequency.

The grid of V1 is metered through metering resistors R1 and R2 at J102-4. The combination of R1, R2 and R3 drops the bias voltage to approximately -11 volts to protect V1 against loss of drive. Plate voltage is supplied through R7 and L1/L2.

When measuring grid current to VI, there will be a residual reading of approximately 0.16 volts without any drive. This is caused by the presence of fixed bias voltage to the grid of the tube.

POWER AMPLIFIER

The output of the MULT-3 stage is coupled through L1/L2 and L6/L7 to the grids of the two compactron beam power amplifiers (V101 and V102) operating in parallel. PA grid drive is metered at J102-6 and J102-14 by measuring voltage drop across R11. Bias voltage (-45)volts is applied to the PA grids through R8, R11 and L6/L7. There is no residual reading on the PA.

Plate current is metered from J102-1 to J102-9 across metering resistor R102. Plate voltage is supplied through L101. The PA plate tank is shunt-tuned by capacitor C110/C112. R18, R19, R21, and R22 are the screen grid dropping resistors.

— WARNING —

The meter leads are at plate potential (high-B+) when metering the PA plate at J102-1 and J102-9.

Placing the TUNE-OPERATE switch (S102) in the OPERATE position applies 300 volts to A145/A146/A147-J3 and -J7. The 300 volts appearing on each side of R17 effectively shorts the resistor out of the circuit, and R18 and R19 (for V101) and R21 and R22 (for V102) are in series for normal operation of V101 and V102. When S102 is in the TUNE position, the screen voltage is applied to J3 only. Now, dropping resistors R17, R18 and R19 (for V101) and R11, R21 and R22 (for V102) are in series to reduce the screen voltage. This reduces the plate dissipation of V101 and V102 while tuning the power amplifier stage. Feedback through C122 neutralizes the stage.

Antenna coupling is achieved by varying the coupling between L115, L116, L117 and L110/L111/L112. The antenna circuit is tuned by C111.

The RF output from the antenna coil is fed to low-pass filter FL101/FL102/FL103. This filter has a low insertion loss and a harmonic attenuation of at least -50 db through all harmonics. The filter output is fed to the antenna changeover relay located on the front of the system frame.

CHANNEL GUARD TRANSMITTER (G101)

The Channel Guard encoder (G101) is assembled on a printed wiring board that mounts on the underside of the MASTR transmitter. The encoder is supplied by a regulated 10 volts and a regulated 20 volts. The 10-volt supply is applied to Q1 and Q2 continuously (even in the STANDBY position), and the 20 volts is applied to Q3 and Q4 only when the transmitter is keyed.

Transistors Q1 and Q2 with reed FL1 are the tone oscillator portion of the circuit. The reed is resonant at the desired tone frequency. Clipping diodes CR1 and CR2 shape the output of the oscillator circuit into a square wave, which is coupled through the Channel Guard TONE ADJUST Control (R12) to the base of Q3. R12 will not require adjustment unless the Channel Guard tone frequency is changed. Then R12 must be set to the new reed frequency.

Q3 and Q4 form a two-section low-pass filter that removes the distortion in the square wave, producing a sine wave output. The square wave oscillator output has a constant amplitude, making the encoder less sensitive to shock and vibration. The encoder tone is fed to the tone modulator on the Exciter Board through Channel Guard MOD ADJ R20.

The Channel can be monitored by moving the CG-OFF SWITCH on the Control Unit to the OFF Position (or by removing the microphone or hand-set from the optional hang-up bracket).

NOTE -

If the Two-Way Radio is mounted vertically or at an angle of over 45° rotate the encoder reed 90° in its mounting bracket so that the label with the G-E Drawing and Part Number is facing the rear of the Two-Way Radio. See Figure 3 for location of the encoder reed.

MAINTENANCE

DISASSEMBLY

To service the transmitter from the top -

- Pull locking handle down and 1. pull radio about one inch out of mounting frame.
- Pry up cover at rear of trans-2. mitter.
- 3. Slide cover back and lift off.

To service the transmitter from the bottom-

- 1. Pull locking handle down. Pull radio out of mounting frame.
- 2. Remove two screws in bottom cover. Prv up at back of transmitter.
- 3. Slide cover back and lift off.

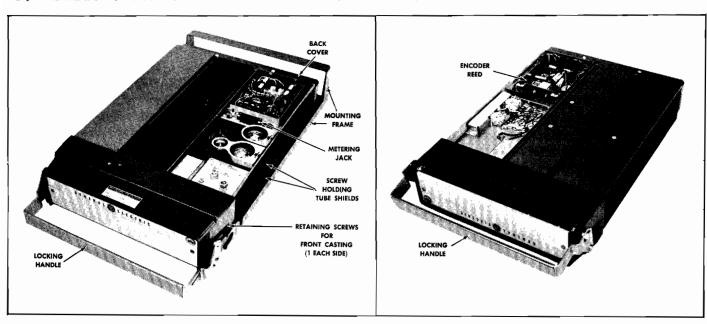


Figure 2 - Top Cover Removed Figure 3 - Bottom Cover Removed

NOTE -

To replace tubes, loosen screws holding tube shields and slide shields off.

To remove transmitter from system frame—

- 1. Loosen the two retaining screws in the front casting (see Figure 2) and pull casting away from the system frame.
- 2. Remove the four screws in the back cover.
- 3. Remove the two screws holding the transmitter at each end of the system frame.
- Disconnect the antenna jack in front of the transmitter and the 4. 20-pin feed-through connector at the back of the transmitter, and slide the unit out of the system frame.

MODULATION LEVEL ADJUSTMENT

The MOD ADJUST (R14) was adjusted to the proper setting before shipment and should not normally require readjustment. This setting permits approximately 75% modulation for the average voice level. The audio peaks which would cause overmodulation are clipped by the modulation limiter. The limiter, in conjunction with the de-emphasis network, instantaneously limits the slope of the audio wave to the modulator, thereby preventing overmodulation while preserving intelligibility.

TEST EQUIPMENT

- 1. An audio oscillator
- 2. A frequency modulation monitor
- 3. An output meter or a VTVM
- 4. G-E Test Set, Model 4EX3Al

PROCEDURE

- 1. Connect the audio oscillator and the meter across audio input terminals J5 (Green-Hi) and J6 (Black-Lo) on G-E Test Set or across J1 (Mike High) and J2 (Mike Low) on the Exciter Board.
- 2. Apply a 1.0-volt signal at 1000 cps to Test Set or across J1 and J2 on Exciter Board.
- 3. For transmitters without Channel Guard, set the MOD ADJUST (R14) for a 4.5-kilocycle swing with the deviation polarity which gives the highest reading as indicated on the frequency modulation monitor.
- 4. For transmitters with Channel Guard, set the Channel Guard MOD ADJUST (R20) for 0.75-KC tone deviation. Then repeak L1/L2 and L3/L4 as shown in Step 1 of Transmitter Alignment Procedure. Reset tone deviation to 0.75 KC deviation. Remove the tone to the transmitter by unplugging leads to J7 and J8 on Exciter Board, or by switching to a non-Channel Guard frequency in multifrequency units. Next, apply a 1.0 volt signal at 1000 cps and set MOD ADJUST (R14) for 3.75-KC deviation (4.5 KC minus 0.75-KC tone deviation).
- 5. For multifrequency transmitters, set the deviation as described in Steps 3 or 4 on the channel producing the largest amount of deviation.

PA POWER INPUT

For FCC purposes, the PA power input can be determined by measuring the PA Plate voltage and the plate current indication, and using the following formula:

P_i = Plate Voltage X Plate Current Indication 2.5

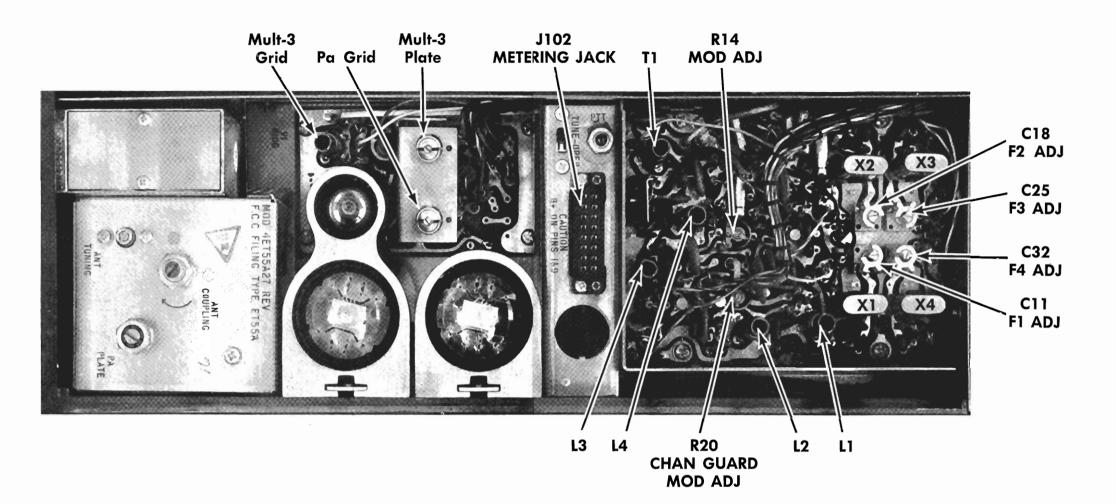
where:

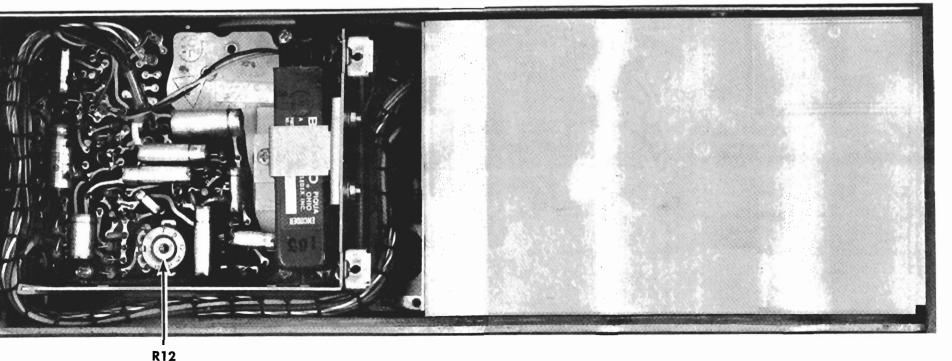
P; is the power input in watts

Plate voltage is measured with G-E Test Set in position G, using the 1000-volt scale (or measured from J102-1 to -16 with multimeter).

Plate current indication is measured with G-E Test Set in position G, using the TEST 1 scale (or measured from J102-1 to -9 with multimeter).

2.5 is the value of the plate current metering resistor in ohms.





CHAN GUARD TONE ADJ

TRANSMITTER ALIGNMENT

EQUIPMENT REQUIRED

 General Electric Test Set Model 4EX3AlO, Station Metering Switching Panel or a 20,000 ohms-per-volt Multimeter with a 1-volt scale.

PRELIMINARY CHECKS AND ADJUSTMENTS

METERING POSITION

- 1. Place crystal (operating frequency ÷ 12) in crystal socket XY1.
- 2. Set crystal trimmer Cll to mid-capacity. If multi-frequency transmitter, set all trimmers to mid-capacity and tune transmitter on channel with the highest frequency (except for Step 7).
- 3. Place the TUNE-OPERATE switch (S102) in the TUNE position.
- 4. Connect Test Set Model 4EX3AlO to the Transmitter Centralized Metering Jack J102. If using Multimeter, connect the positive lead to J102-16 (Ground) except for Steps 6 through 14.

TYPICAL

- 5. For a large change in frequency or a badly misaligned transmitter, set the slugs in all slug-tuned coils in the center of the coil form. All slugs will then tune clockwise, except MULT-3 PLATE and PA GRID slugs which tune counterclockwise.
- 6. All adjustments are made with the transmitter keyed.

STEP	4EX3A10	Multimeter - at J102	TUNING CONTROL	METER READING	DROCEDURE
SIEP	4EASH10	- at 5102	TONING CONTROL		PROCEDURE CITER BOARD
1.	A	Pin 10	Ll (and L2 with	0,6 v	Tuning the modulator is a critical adjustment. Carefully tune
1.	(MULT-1)	7111 10	Channel Guard)	(0.4 v Minimum)	Ll for maximum meter reading. For transmitters with Channel Guard, alternately tune Ll and L2 for maximum meter reading.
2.	A (MULT-1)	Pin 10	L3	See pro- cedure	Tune L3 for a small peak in meter reading (not required unless changing frequency).
3.	B (MULT-2)	Pin 2	L4 and L3	0.65 v (0.4 v Minimum)	Tune L4 and then L3 for maximum meter reading. Then tune Tl for minimum meter reading (not required unless changing frequency).
					NOTE
					Misalignment of this coil may result in the remainder of the transmitter being tuned off frequency. Always start with the slug in the center of the coil form (at maximum inductance) and tune for the first peak.
				MULT-3 AN	D POWER AMPLIFIER
4.	D (MULT-3)	Pin 4	MULT-3 GRID and T1 (on Exciter)	0.55 v (0.4 v Minimum)	Alternately tune MULT-3 GRID and Tl (on Exciter) for maximum meter reading. Then tune MULT-3 PLATE for slight change in meter reading (not required unless changing frequency).
5.	F (PA GRID)	Pin 14 (+) and Pin 6 (-)	PA GRID and MULT-3 PLATE	0.45 v (0.4 v Minimum)	Alternately tune PA GRID and MULT-3 PLATE for maximum meter reading.
6.					Rotate ANT COUPLING fully counterclockwise.
7.	G (PA PLATE)		RNING on Pins 1 and 9.	Minimum	For single-frequency transmitters, carefully tune PA PLATE for minimum meter reading.
		Pin 1 (+) and Pin 9 (-)	PA PLATE		For multi-frequency transmitters, switch to the lowest frequency and adjust PA PLATE for minimum meter reading.
8.					Place S102 in the OPERATE position.
9.	G (PA PLATE)	Pin 1 (+) and Pin 9 (-)	ANT COUPLING	See pro- cedure	Rotate ANT COUPLING clockwise until meter reading rises slightly. In multi-frequency transmitters, switch back to the highest frequency before tuning ANT COUPLING.
10.	G (PA PLATE)	Pin 1 (+) and Pin 9 (-)	ANT TUNING	Maximum	Adjust ANT TUNING for maximum meter reading.
11.	G (PA PLATE)	Pin 1 (+) and Pin 9 (-)	ANT COUPLING	0.7 v	Adjust ANT COUPLING for metering reading of 0.7 volts.
12.	F (PA GRID)	Pin 14 (+) and Pin 6 (-)	PA GRID	Maximum	Readjust PA GRID for maximum meter reading.
				FREQUE	ENCY ADJUSTMENT
13.			C11, (C18, C25 an C32 in multi-fre- quency units)		With no modulation, adjust crystal trimmer Cll (on Exciter) for proper oscillator frequency. In multi-frequency units, adjust Cl8, C25 and C32 as required. Next, refer to the MODULATION ADJUSTMENT.

ALIGNMENT PROCEDURE

25 — 50 MC, 100-WATT MASTR TRANSMITTER MODELS 4ET55A10-27

Issue 3

LBI-3580

LBI-3580

TEST PROCEDURES

servicing a transmitter that is operating--but not properly. vice Check!' and the additional corrective measures included Problems encountered could be low power output, low B plus, in the Transmitter Troubleshooting Procedure. Before starttone and voice deviation, defective audio sensitivity and modu- ing with the Transmitter Test Procedures, be sure the translator adjust control set too high. By following the sequence mitter is tuned and aligned to the proper operating frequency.

These Test Procedures are designed to assist you in localized. Once a defect is pin-pointed, refer to the "Ser-

of test steps starting with Step 1, the defect can be quickly

TEST EQUIPMENT REQUIRED

for test hookup as shown:

1. Wattmeter similar to: 2. VTVM similar to: 3. Audio Generator similar to: 4. Deviation Meter (with a .75 KC scale)

Triplett #850

Heath#1G-72

similar to: Measurements #140 Lampkin #205A

Multimeter similar to:

Heath #1M-21

G-E METERING TEST SET MODEL 4EX3A10 or Triplett #631 or 20,000 ohms-per-volt voltmeter

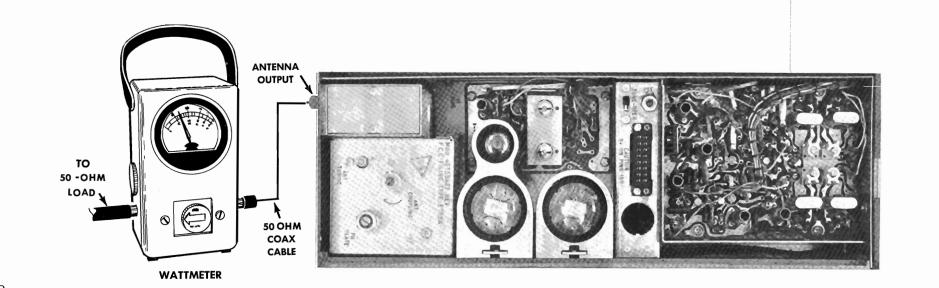
STEP 1

POWER MEASUREMENT TEST PROCEDURE

Bird #43

Jones #711N

Connect transmitter output to wattmeter as shown below:



2. Key transmitter and check wattmeter for minimum reading of 100 watts.

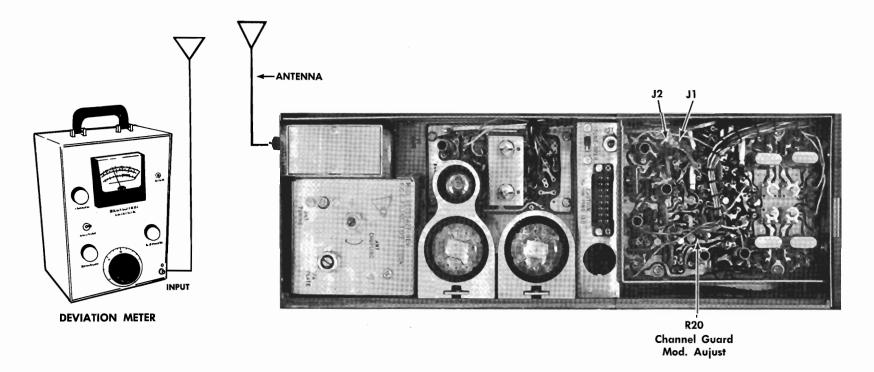
SERVICE CHECK

Refer to Service Hints on Transmitter Troubleshooting Procedure.

STEP 2

TONE DEVIATION WITH CHANNEL GUARD TEST PROCEDURE

1. Setup Deviation Meter and monitor output of transmitter as shown below:

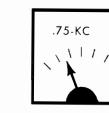


- 2. Unplug the MIC HI terminal from Jl on Transmitter Exciter Board.
 - Key transmitter and check for 0.75-KC deviation. If reading is low or high, adjust Channel Guard MOD ADJUST (R20) for a reading of 0.75 KC.

NOTES:

The Channel Guard MOD ADJUST (R20) may be adjusted for deviations up to 0.80 KC for tone frequencies from 71.9 cps to 82.5 cps, and deviations up to 1.0 KC for all tone frequencies above 82.5 cps.

DEVIATION METER



NOTES:

- 1. On units supplied with Channel Guard, the Phase Modulator Tuning should be peaked carefully to insure proper performance. (Refer to Steps 1 and 2 in the Transmitter Alignment Chart).
- 2. The Tone Deviation Test Procedures should be repeated every time the Tone Frequency is changed.

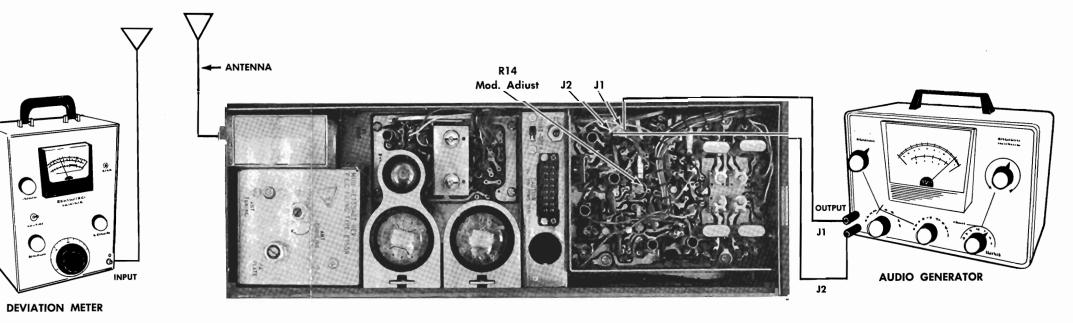
SERVICE CHECK

If the 0.75-KC deviation is not obtainable when adjusting R20, replace the Tone Transmitter reed.

STEP 3

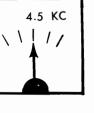
VOICE DEVIATION AND SYMMETRY TEST PROCEDURE

- Unplug the High and Low Mike leads from the Exciter Board Jacks Jl and J2.
- Connect test equipment to transmitter as shown below:



- Set the generator output to 1.0 VOLTS RMS and frequency to 1 KC.
- Key the transmitter and adjust Deviation Meter to carrier frequency.
- Deviation reading should be ±4.5 KC.
- Adjust ''Modulation Adjust Control' R14 until deviation reads 4.5 KC on plus (+) or minus (-) deviation, whichever is greater. This adjustment should be made with the correct level of tone applied on Channel Guard transmitters.

DEVIATION METER

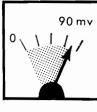


NOTES: -- MASTR transmitters are adjusted for 4.5 KC deviation at the factory. The factory adjustment will prevent the transmitter from deviating more than 5.0 KC under the worst conditions of frequency, voltage and temperature.

If the deviation reading plus (+) and minus (-) differs by more than 0.5 KC, check the following:

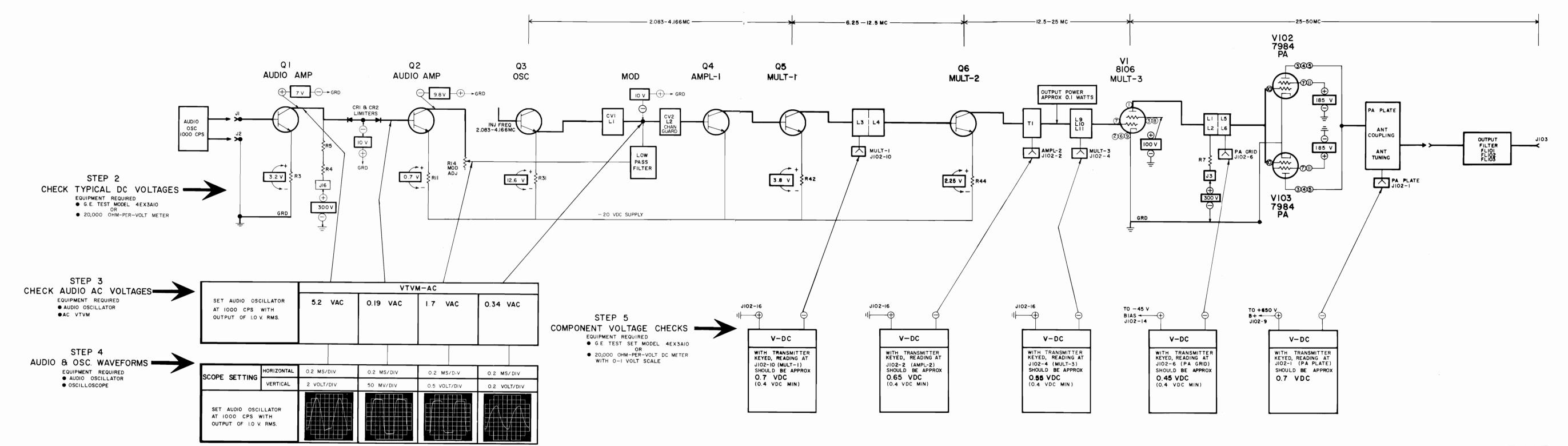
- 1. Recheck Step 1 as shown in the Transmitter Alignment Chart.
- 2. Check Audio Sensitivity by reducing generator output until deviation falls to 3.3 KC. Voltage should be LESS than 90 millivolts.





STEP I - QUICK CHECKS

C.	HECK VOLT	AGES AT (Multime GE Test	eter = pi Set = A	n number	rs		
POWER OUTPUT	Pins 10 & 16 A	Pins 2 & 16 B	Pins 4 & 16 D	Pins 6 & 14 F	Pins 1 & 9 G	PROBABLE DEFECT	
Low	0.7 v	0.65 v	0.6 v	0.4 v	0.7 v	Weak 7984	
0	0.7 v	0.65 v	0.6 v	0	0	Open 7984	
Low	0.7 v	0.65 v	0.6 v	Low or neg.		Weak 8106	
0	0.7 v	0.65 v	0.15 v	0	0.4 v	8106 Fil. open	
0	0.7 v	0.65 v	0.15 v	0	0	Open Fil. Fuse	
0	0.7 v	0 or over 1.0 v	0.15 v	0	0.4 v	Defective Q6	
0	Over 1.0 v	0	0.15 v	0	0.4 v	Shorted Q5 or Open Q4	
0	0	0	0.15 v	0	0.4 v	Defective Q3- or Modulator (See note A)	
NOTE A	Local	lize trou	ble by ch	necking:			
1.	-20 v	olt DC s	upply at	J102-12	-16.	-	
2.	Measu then		VDC acros	ss Q3 em	itter r	esistor R31,	
(a)		Remove crystal - a slight variation in R31 voltage reading indicates Q3 stage operating properly.					
(b)		voltage CR6, Q3.	is meası	ıred, ch	eck key	ing leads	
(c)	A vol Q5 ar	With crystal removed, short Q4 base to emitter. A voltage reading above 1.0 volt indicates Q4 and Q5 are operating properly. Defect may be in Modulator.					
(d)		odulator :		tive, ch	eck vol	tage variable	

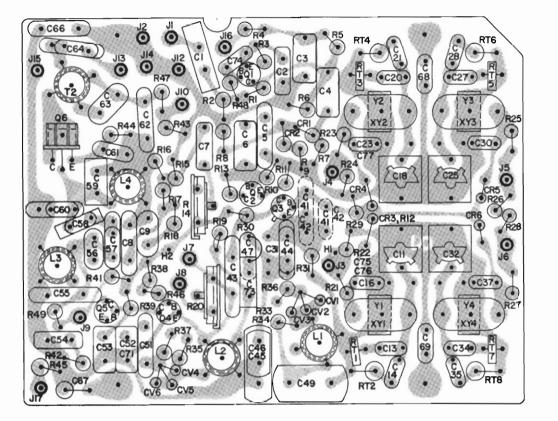


TROUBLESHOOTING PROCEDURE

Issue

25 — 50 MC, 100-WATT MASTR TRANSMITTER MODELS 4ET55A10-27

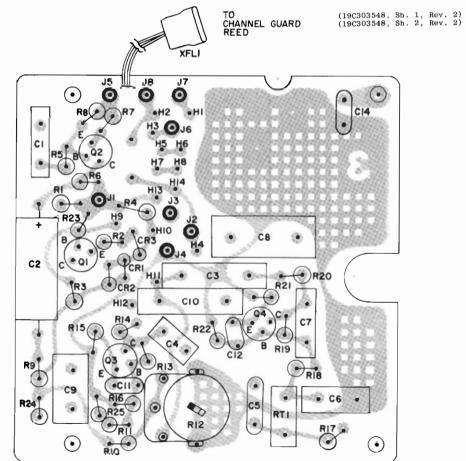
EXCITER



RUNS ON SOLDER SIDE

RUNS ON BOTH SIDES

RUNS ON COMPONENT SIDE



CHANNEL GUARD

(19C303456, Sh. 1, Rev. 3) (19C303456, Sh. 2, Rev. 3)

OUTLINE DIAGRAM

25 — 50 MC, 100-WATT MASTR TRANSMITTER MODELS 4ET55A10-27

Issue 4

 Q1
 6.4k
 6.8k
 200K
 12K
 65K
 22K

 Q2
 8.5K
 5K
 70K
 13K
 10K
 10K

 Q3
 10K
 6.5K
 20K
 2.9K
 100
 1QD

 Q4
 6.5K
 3.1K
 80K
 8K
 4.2K
 2.5K

 05
 7K
 3.8K
 4.2K
 2.5K
 170Ω
 170Ω

 Q6
 6.7K
 3.3K
 6.5K
 3.1K
 70
 70

EXCITER READINGS TAKEN TO CHASSIS GROUND

CITER REA	ADINGS	TAKEN 1	0 -200	LINE (_ BLUE)	
ANSISTOR	EMIT	TER	BA	SE	COLLECTOR		
		+	-	+	-	+	
Õ1	13K	12K	220K	45K	3.1K	6.5K	
Q2	1.2K	1.2K	65K	4.7K	16 K	2 2 K	
Q3	2.0K	2K	6.2 K	5.5K	3.3K	6.6K	
Q 1	0	0	3.3K	3.4K	IOK	4. IK	
Q5	340	390	IOK	4.1K	3.4K	6.BK	
Q6	60	120	0	0	3K	6.6K	

RESISTANCE READINGS

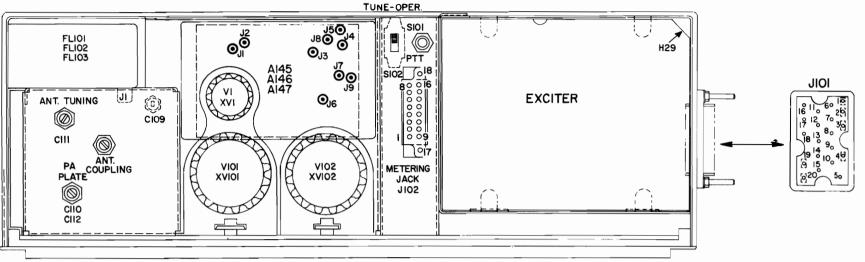
ALL READINGS ARE TYPICAL READINGS MEASURED WITH A 20,000 OHM-PER-VOLT METER AND JIOI DISCONNECTED. + OR — SIGNS SHOW METER LEAD GROUNDED.

FOR READINGS OF:	USE SCALE
1-100Ω	X I
100-1ΚΩ	X IO
IK-50KΩ	X 1,000
50- ∞Ω	X 100.000

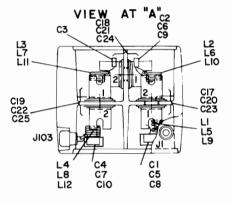
CHANNEL (SUARD !	READIN	S MEAS	SURED .	то сни	ASSIS GD
TRANSISTOR	EMI	TTER	В,	ASE	COL	LECTOR
	+	_	+	-	+	-
Q١	00	∞	000	∞	∞	∞
Q2	∞	∞	~	∞	∞	∞
Q3	2.7K	4.9K	9.5k	30K	8.4K	7 . 5K
Órt	2.7K	4.9K	6к	24K	2.5K	2.6K
		•				

	Т		GUARD R		ORANGE	ED		
TRANSISTOR	EMI	TTER	84	SE	COLLI	COLLECTOR		
	+	_	+	-	+	<u> </u>		
QI	200	200	9к	14K	2.7K	25K		
Q2	1.3K	1.3K	3.4K	6.3K	15K	8.7K		
Q3	8	~	∞	~	∞	000		
Q4	∞	∞	∞	∞	∞	∞		

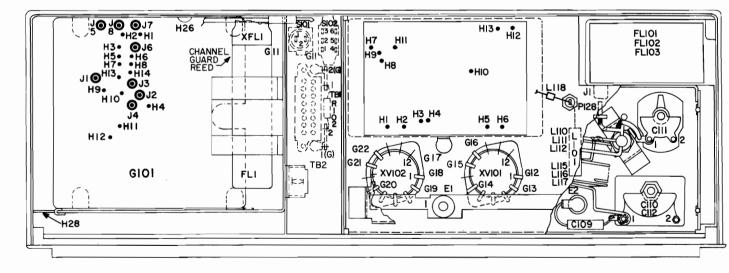
TOP VIEW

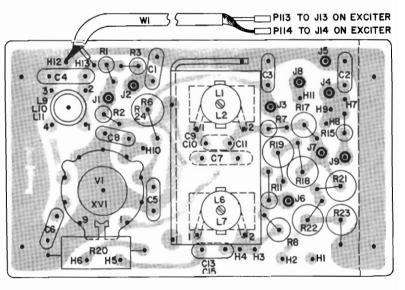


		S AT JIOL T SIS GROUND	TAKFN
P	I N	_	+
	ı	0	0
	2	~	~
	3	1.3Ω	1.3Ω
	14	27 K	27K
	5	90	∞
	6		∞
	7	~	~
	8	70 K	70K
	. 9	~	~
	10	~	∞
	Н	000	~
	12	30K	16K
	13	~	∞
	14	∞	~
	15	6.5K	3. IK
	16	∞/30K €	∞/16K
	17	∞/3 0 K	∞/16K
	18	∞/30K	∞/16K
	19	0	0
	20	00	∞



BOTTOM VIEW



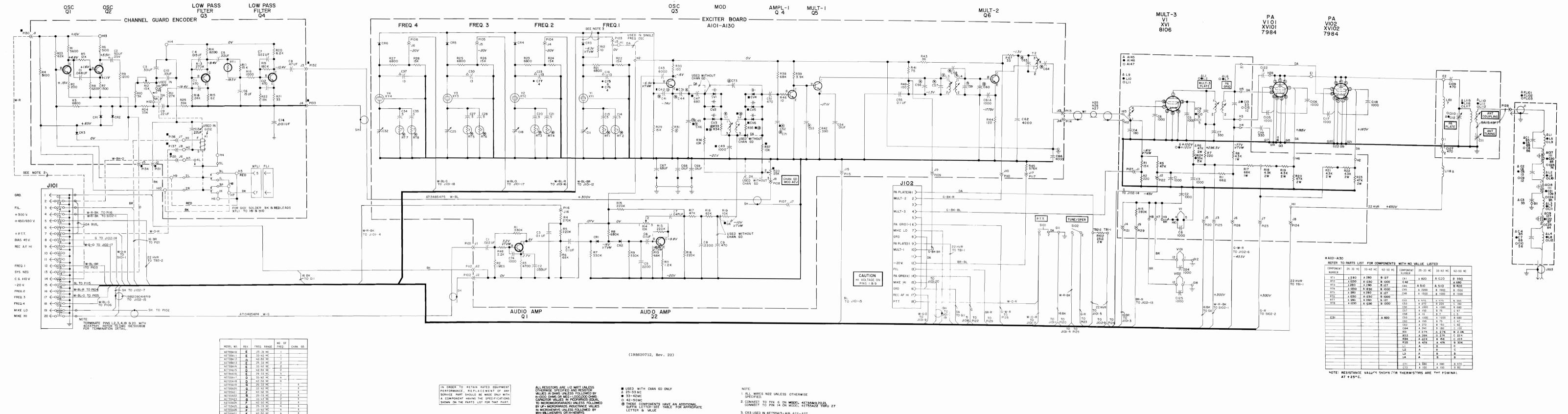


A145 - A147

19B204613, Sh. 1, Rev. 1

READINGS FROM TUBE SOCKET PINS TO CHASSIS GROUND

PIN	ł	2	3	14	5	6	7	8	9	10	11	12
XVI	27K	0	82K	1.3 Ω	0	0	16K	82K	0			
XVIOI	0	0	~	∞	∞	0	27K	0	ō	75K	27K	1.3Ω
XV102	0	0	~	∞	∞	0	27K	0	0	75K	27K	1.3Ω



3. CR3 USED IN 4ET55AI3-AIB; A22-A27. RI2 USED IN 4ET55AI0-AI2; A19-A21.

SCHEMATIC DIAGRAM

25 — 50 MC, 100-WATT MASTR TRANSMITTER MODELS 4ET55A10-27

LBI-3580

LBI-3531B

25-50 MC TRANSMITTER
MODELS 4ET55A10 - 4ET55A36

4ET55A10-18 (PL-19E500808 C28-36) STANDARD, REV. A
4ET55A19-27 (PL-19E500808 G37-45) CHANNEL GUARD, REV. B

PARTS LIST

YMBOL	G-E PART NO.	DESCRIPTION
		SUBASSEMBLIES
A101-103, A106-108, A111-113, A116-118, A121-123, A126-128		EXCITER BOARD ASSEMBLY A101-103 (19D402385 G1-3) (4ET55A10-12) A106-108 (19D402385 G6-8) (4ET55A13-15) A111-113 (19D402385 G11-3) (4ET55A16-18) A116-118 (19D402385 G16-18) (4ET55A19-21) A121-123 (19D402385 G21-23) (4ET55A2-24) A126-128 (19D402385 G26-28) (4ET55A25-27)
Cl	19B209243-P3	Polyester dielectric: radial leads, .022 µf ±20%, 40 YDCW; sim to Amperex C280AA/P22K.
C2*	19B209243-P4	Polyester: 0.033 µf ±20%, 40 VDCW. In Models 4ET55All, 12, 14, 15, 17 and 18 REV. and earlier; in Models 4ET55Al0, 13 and 16 REV. C and earlier; in Models 4ET55A20, 23, 23 24, 26 and 27 REV. D and earlier; and in Model
C3*	19B209243-P3 19B209243-P13	#FIDDAL9, 22 and 25 NeV. E and earlier: Polyester: .022 µf ±20%, 40 VDCW. In Models #FIDDAL2, 15, 17 and 18 REV. C and earlier; in Models #FIDDAL0, 11, 13, 14 and 16 Rev. D a earlier; in Models #FIDDAL2, 24. 26 and 27
	19A115414-P13	REV. E and earlier; and in Models 4ET55A19, 20 22, 23 and 25 REV. F and earlier. Tubular, Mylare dielectric: radial leads, 0.1 µf ±20%, 200 VDCW.
C4	19B209243-P7	Polyester dielectric: radial leads, 0.1 µf ±20%, 40 VDCW; sim to Amperex C280AA/P100K.
C5	7491395-P114	Ceramic disc: radial leads, .0022 µf ±10%, 500 VDCW.
C6	19B209243-P7	Polyester dielectric: radial leads, 0.1 µf ±20%, 40 VDCW; sim to Amperex C280AA/Pl00K.
C7	19B209243-P5	Polyester dielectric: radial leads, .047 µf ±20%, 40 VDCW; sim to Amperex C280AA/P47K.
C8	7491395-P114	Ceramic disc: radial leads, .0022 µf ±10%, 500 VDCW.
C9	5493366-P470J	Silver mica, dipped phen: radial leads, 470 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55A10-18).
C11	5491271-P106	Variable, air dielectric, subminiature: approx 1.98-12.4 pf, 750 v peak; sim to EF Johnson 189-6-5.
C13 and C14	19C300685-P93	Ceramic disc: temp-comp, radial leads, 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.
C16*	5496219-P343	Ceramic: 13 pf ±5%, 500 VDCW, temp coef -150 p
C18	5491271-P106	Variable, air dielectric, subminiature: approx 1.98-12.4 pf, 750 v peak; sim to EF Johnson 189-6-5. (Used in Models 4ET55Al3-18, 22-27, 31-36).
C20 and C21	19C300685-P93	Ceramic disc: temp-comp, radial leads, 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM. (Used in Models 4ET55Al3-18, 22-27, 31-36).
C23*	5496219-P343	Ceramic: 13 pf ±5%, 500 VDCW, temp coef -150 p
C25	5491271-P106	Variable, air dielectric, subminiature: approx 1,98-12,4 pf, 750 v peak; sim to EF Johnson 189-6-5. (Used in Models 4ET55A16-18, 25-27, 34-36).
C27 and C28	19C300685-P93	Ceramic disc: temp-comp, radial leads, 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM. (Used in Models 4ET55A16-18, 25-27, 34-36).
C30*	5496219-P343	Ceramic: 13 pf ±5%, 500 VDCW, temp coef -150 p
C31	5496372-P178	Ceramic disc: temp-comp, radial leads, 820 pf ±5%, 500 VDCW, temp coef -3300 PPM. (Used in Models 4ET55A21, 24, 27, 30, 33 and 36).
C32	5491271-P106	Variable, air dielectric, subminiature: approx 1.98-12.4 pf, 750 v peak; sim to EF Johnson 189-6-5 (Used in Models 4ET55A16-18, 25-27, 34-36).
C34 and C35	19C300685-P93	Ceramic disc: temp-comp, radial leads, 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM. (Used in Models 4ET55A16-18, 25-27, 34-36).
		Ceramic: 13 pf ±5%, 500 VDCW, temp coef -150 P

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES.

YMBOL	G-E PART NO	DESCRIPTION
		SUBASSEMBLIES(Cont'd)
C41A	5496372-P178	Ceramic disc: temp-comp, radial leads, 820 pf 15%, 500 VDCW, temp coef -3300 PPM. (Used in Models 4ET55AlO, 11, 13, 14, 16, 17, 19, 20, 22, 23, 25, 26, 28, 29, 31, 32, 34 and 35).
C41B	5496372-P62	Ceramic disc: temp-comp, radial leads, 390 pf $\pm 5\%$, 500 VDCW, temp coef -2200 PPM. (Used in Models 4ET55A12, 15 and 18).
C42A	4029003-P4	Silver mica, dipped phen: radial leads, 680 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-20. (Used in Models 4ET55A21, 24, 27, 30, 33 and 36).
C43	5494481-P120	Ceramic disc: radial leads, .006 μ f $\pm 10\%$, 500 VDCW; sim to RMC Type JF Discap.
C44A	4029003-P1	Silver mica, dipped phen: radial leads, 510 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-20. (Used in Models 4ET55Al0, 11, 13, 14, 16, 17, 19, 20, 22, 23, 25, 26, 28, 29, 31, 32, 34 and 35).
C44B	4029003-P6	Silver mica, dipped phen: radial leads, 820 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-20. (Used in Models 4ET55Al2, 15 and 18).
C45A	4029003-P16	Silver mica, dipped phen: radial leads, 2200 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-20. (Used in Models 4ET55Al0, 13 and 16).
C45B	4029003-P12	Silver mica, dipped phen: radial leads, 1500 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-20. (Used in Models 4ET55All, 12, 14, 15, 17 and 18).
C46A	4029003-P12	Silver mica, dipped phen: radial leads, 1500 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-20. (Used in Models 4ET55419, 22, 25, 28, 31 and 34).
C46B	4029003-P8	Silver mica, dipped phen: radial leads, 1000 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-20. (Used in Models 4ET55A20, 21, 23, 24, 26, 27, 29, 30, 32, 33, 35 and 36).
C47	5496372-P174	Ceramic disc: temp-comp, radial leads, 680 pf ±5%; 500 VDCW, temp coef -3300 PPM. (Used in Models 4ET55A19-36).
C49	5493367-P1000J	Silver mica, dipped phen: radial leads, .001 µf ±5%, 100 VDCW; sim to Electro Motive Type DM-20. (Used in Models 4ET55A19-36).
C51	5496372-P66	Ceramic disc: temp-comp, radial leads, 470 pf ±5%, 500 VDCW, temp coef -2200 PPM.
C52A	5493366-P470K	Silver mica, dipped phen: radial leads, 470 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55A19, 20, 22, 23, 25, 26, 28, 29, 31, 32, 34 and 35).
C52B	5493366-P390K	Silver mica, dipped phen: radial leads, 390 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55A21, 24, 27, 30, 33 and 36).
C53A	5493366-P270K	Silver mica, dipped phen: radial leads, 270 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55A10, 13, 16, 19, 22, 25, 28, 31 and 34).
C53B	5493366-P220K	Silver mica, dipped phen: radial leads, 220 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55All, 14, 17, 20, 23, 26, 29, 32 and 35).
C53C	5493366-P180K	Silver mica, dipped phen: radial leads, 180 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55A12, 15, 18, 21, 24, 27, 30, 33 and 36).
C54	19B209243-P1	Polyester dielectric: radial leads, .01 µf ±20%, 40 VDCW; sim to Amperex C280AA/PlOK.
C55	7491827-P5	Ceramic disc: radial leads, 0.1 µf +80% -30%, 50 VDCW; sim to Sprague 36C172.
C56A	5493366-P1000J	Silver mica, dipped phen: radial leads, .001 μ f ±5%, 100 VDCW; sim to Electro Mottive Type DM-15. (Used in Models 4ET55Al0, 11, 13, 14, 16, 17, 19, 20, 22, 23, 25, 26, 28, 29, 31, 32, 34 and 35).
C56B	5493366-P680J	Silver mica, dipped phen: radial leads, 680 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55A12, 15, 18, 21, 24, 27, 30, 33 and 36).

SYMBOL	G-E PART NO	DESCRIPTION
		SUBASSEMBLIËS(Cont'd)
		CAPACITORS(Cont'd)
C57A	5496219-P767	Ceramic disc: temp-comp, radial leads, 150 pf 15%, 500 VDCW, temp coef -750 PPM. (Used in Models 4ET55Al0, 13, 16, 19, 22, 25, 28, 31 and 34).
C57B	5496219-P860	Ceramic disc: temp-comp, radial leads, 75 pf ±5%, 500 VDCW, temp coef -1500 PPM. (Used in Models 4ET55All, 14, 17, 20, 23, 26, 29, 32 and 35).
C57C	5496219-P855	Ceramic disc: temp-comp, radial leads, 47 pf ±5%, 500 VDCW, temp coef -1500 PPM. (Used in Models 4ET55Al2, 15, 18, 21, 24, 27, 30, 33 and 36).
C58A	5496219-P41	Ceramic disc: temp-comp, radial leads, 10 pf ±5%, 500 VDCW, temp coef 0 PPM. (Used in Models 4ET55Al0, 13, 16, 19, 22, 25, 28, 31 and 34).
C58B	5496219-P38	Ceramic disc: temp-comp, radial leads, 7 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM. (Used in Models 4ET55All, 14, 17, 20, 23, 26, 29, 32 and 35).
C58C	5496219-P36	Ceramic disc: temp-comp, radial leads, 5 pf ±0.25 pf, 500 YDCW, temp coef 0 PPM. (Used in Models 4ET55Al2, 15, 18, 21, 24, 27, 30, 33 and 36).
C59A	5493366-P1000J	Silver mica, dipped phen: radial leads, .001 µf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55Al0, 11, 13, 14, 16, 17, 19, 20, 22, 23, 25, 26, 28, 29, 31, 32, 34 and 35).
C59B	5493366-P680J	Silver mica, dipped phen: radial leads, 680 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55Al2, 15, 18, 21, 24, 27, 30, 33 and 36).
C60A	5496219P767	and 36). Ceramic disc: temp-comp, radial leads, 150 pf ±5%, 500 YDCW, temp coef -750 PPM. (Used in Models 4ET55A10, 13, 16, 19, 22, 25, 28, 31 and 34).
C60B	5496219-P860	Ceramic disc: temp-comp, radial leads, 75 pf ±5%, 500 VDCW, temp coef -1500 PPM. (Used in Models 4ET55All, 14, 17, 20, 23, 26, 29, 32 and 35).
C60C	5496219-P855	Ceramic disc: temp-comp, radial leads, 47 pf ±5%, 500 VDCW, temp coef -1500 PPM. (Used in Models 4ET55A12, 15, 18, 21, 24, 27, 30, 33 and 36).
C61A	5494481-P112	Ceramic disc: radial leads, .001 µf ±10%, 500 VDCW; sim to RMC Type JF Discap.
C62	5494481-P118	Ceramic disc: radial leads, .004 µf ±10%, 500 VDCW; sim to RMC Type JF Discap.
C63A	5493366- P 270 J	Silver mica, dipped phen: radial leads, 270 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55AlO, 13, 16, 19, 22, 25, 28, 31 and 34).
С63В	5493366-P150J	Silver mica, dipped phen: radial leads, 150 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55All, 14, 17, 20, 23, 26, 29, 32 and 35).
C63C	5493366-P82J	Silver mica, dipped phen: radial leads, 82 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55Al2, 15, 18, 21, 24, 27, 30, 33 and 36),
C64A	5496219-P772	Ceramic disc: temp-comp, radial leads, 240 pf ±5%, 500 YDCW, temp coef -750 PPM. (Used in Models 4ET55AlO, 13, 16, 19, 22, 25, 28, 31 and 34).
C64B	5496219-P769	Ceramic disc: temp-comp, radial leads, 180 pf ±5%, 500 VDCW, temp coef -750 PPM. (Used in Models 4ET55All, 14, 17, 20, 23, 26, 29, 32 and 35).
C64C	5496219-P763	Ceramic disc: temp-comp, radial leads, 100 pf ±5%, 500 VDCW, temp coef -750 PPM. (Used in Models 4ET55Al2, 15, 18, 21, 24, 27, 30, 33 and 36).
C66	5494481-P118	Ceramic disc: radial leads, .004 µf ±10%, 500 VDCW; sim to RMC Type JF Discap.
C67	5496267-P18	Tubular, hermetically sealed, tantalum, dry solid: axial leads, 6.8 µf ±20%, 35 VDCW; sim to Sprague 150D685X0035B2.

SYMBOL	G-E PART NO	DESCRIPTION
		SUBASSEMBLIES(Cont'd)
		CAPACITORS(Cont'd)
C68 and C69	7491827-P2	Ceramic disc: radial leads, .01 μf +80% -30%, 50 VDCW; sim to Sprague 19C180.
C71A	5493366-P680J	Silver mica, dipped phen: radial leads, 680 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55AlO, 11, 13, 14, 16 and 17).
C71B	5490008-P43	Silver mica, dipped phen: radial leads, 470 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ET55A12, 15 and 18).
C73A	5490008-P27	Silver mica, dipped phen: radial leads, 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. (Used in Models 4ETS5AD, 11, 13, 14, 16 and 17).
С73В	5490008-P25	Silver mica, dipped phen: radial leads, 82 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. (Used in Models
C74	5494481-P112	4ET55Al2, 15 and 18). Ceramic disc: radial leads, .001 μf ±10%, 500 VDCW; sim to RMC Type JF Discap.
C75*	5496219-P37	500 VDCW; sim to RMC Type JF Discap. Ceramic disc: 6pf ±0.25 pf, 500 VDCW.
		(Used in Models 4ET55All and 20).
C76* and C77	5496219- ₽ 35	Ceramic disc: 4 pf ± 0.25 pf, 500 VDCW, temp coef 0 PPM. (Used in Models 4ET55Al4 and 23).
on-	104115011	DIODES AND RECTIFIERS
CR1 and CR2	19A1153;1-P1	Silicon.
CR3 and CR4	19A1156#3-P1	Silicon (Used in Models 4ET55A13-18, and 22 - 27)
CR5 and CR6	19A1156#3-P1	Silicon. (Used in Models 4ET55A16-18, 25-27, 34-36).
C V 1*	5495769-P8	Silicon: capacitive. In Models 4ET55Al2, 15 17, and 18 REV. C and earlier: in Models 4ET55Al0, 11, 13, 14 and 16 REV. D and earlier in Models 4ET55A2l, 24, 26 and 27 REV. E and
	5495769-P13	ARISSALU, II, 13, 14 and 16 kRV. D and earlier in Models 4ET55A21, 24, 26 and 27 REV. E and earlier; and in Models 4ET55A19, 20, 22, 23 an 25 REV. F and earlier. Silicon: capacitive.
CV2*	5495769-P8	Silicon: capacitive. In Models 4ET55A21, 24, 26 and 27 REV. E and earlier; and in Models 4ET55A19, 20, 22, 23 and 25 REV. F and earlier
	5495769-P13	Silicon: capacitive. (Used in Models 4ET55Al9-36).
CV3*	5495769-P8	Silicon: capacitive.
CV4* CV6	549576⊊₽8	Silicon: capacitive. (Used in Models 4ET55A19-27).
Lla	PL-19C303526-G1	Coil. (Used in Models 4ET55Al0, 13, 16, 19, 22, 25, 28, 31 and 34). Includes:
	5491798-P2	Tuning slug.
LlB	PL-19C3(3526-G2	Coil. (Used in Models 4ET55All, 14, 17, 20, 23, 26, 29, 32 and 35). Includes:
	5491798-P2	23, 26, 29, 32 and 35). Includes: Tuning slug.
LlC	PL-19C3(3526-G3	Coil. (Used in Models 4ET55A12, 15, 18, 21, 24, 27, 30, 33 and 36). Includes:
	5491798-P2	24, 27, 30, 33 and 36). Includes: Tuning slug.
L2A	PL-19C3)3526-G1	Coil. (Used in Models 4ET55Al9, 22, 25, 28,
	5491798-P2	31 and 34). Includes: Tuning slug.
L2B	PL-19C363526-G2	Coil. (Used in Models 4ET55A20, 23, 26, 29, 32 and 35). Includes:
	5491798-P2	Tuning slug,
	1	
L2C	PL-19C3(3526-G3	Coil. (Used in Models 4ET55A21, 24, 27, 30, 33 and 36). Includes:

MBOL	G-E PART NO	DESCRIPTION
		SUBASSEMBLIES(Cont'd)
		INDUCTORS(Cont'd)
L3A	PL-19B204649-G1	Coil. (Used in Models 4ET55Al0, 13, 16, 19, 22, 25, 28, 31 and 34). Includes:
	5491798- P4	22, 25, 28, 31 and 34). Includes: Tuning slug.
L3B	PL-19B204650-G1	Coil. (Used in Models 4ET55All, 12, 14, 15, 17, 18, 20, 21, 23, 24, 26, 27, 29, 30, 32, 33, 35 and 36). Includes:
	5491798-P4	Tuning slug.
L4A	PL-19B204649-G2	Coil. (Used in Models 4ET55Al0, 13, 16, 19, 22, 25, 28, 31 and 34). Includes:
	5491798- P 4	Tuning slug.
L4B	PL-19B204650-G3	Coil. (Used in Models 4ET55All, 12, 14, 15, 17, 18, 20, 21, 23, 24, 26, 27, 29, 30, 32, 33, 35 and 36). Includes:
	5491798-P4	Tuning slug.
Q1 and	19All5123-Pl	TRANSISTORS Silicon, NPN; sim to Type 2N2712.
Q2 Q3 and	19A115330-P1	Silicon, NPN.
Q4 Q5	19A115328-P1	Silicon, NPN.
Q6*	19A115328-P1	Silicon: NPN. In Models 4ET55A12, 15, 17 and 18 REV. C and earlier; in Models 4ET55A10, 11, 13, 14 and 16 REV. D and earlier; in Models 4ET55A21, 24, 26 and 27 REV. E and earlier; and in Models 4ET55A19, 20, 22, 23 and 25 REV. F
	19A115329-P1	and earlier: Silicon: NPN.
Rl	3R77-P334K	Fixed composition: 0.33 megohm ±10%, 1/2 w.
R2	3R77-P105K	Fixed composition: 1 megohm $\pm 10\%$, $1/2$ w.
R3*	3R77-P472K	Fixed composition: 4700 ohms ±10%, 1/2 w. In Models 4ET55A11, 12, 14, 15, 17 and 18 REV. B and earlier; in Models 4ET55A10, 13 and 16 REV. C and earlier; in Models 4ET55A20, 21, 23, 24, 26 and 27 REV. D and earlier; and in Models 4ET5SA19, 22 and 25 REV. E and earlier
	3R77-P682K	Fixed composition: 6800 ohms ±10%, 1/2 w.
R4	3R77-P274K	Fixed composition: 0.27 megohm ±10%, 1/2 w.
R5 R6	3R77-P224K 3R77-P683K	Fixed composition: 0.22 megohm $\pm 10\%$, $1/2$ w. Fixed composition: 68,000 ohms $\pm 10\%$, $1/2$ w.
R7	3R77-P334K	Fixed composition: 68,000 ohms ±10%, 1/2 w. Fixed composition: 0.33 megohm ±10%, 1/2 w.
R8	3R77-P684K	Fixed composition: 0.68 megohm ±10%, 1/2 w.
R9	3R77-P334K	Fixed composition: 0.33 megohm ±10%, 1/2 w.
R10	3R77-P683K	Fixed composition: 68,000 ohms ±10%, 1/2 w.
Rll	3R77-P122K	Fixed composition: 1200 ohms $\pm 10\%$, $1/2$ w.
R12*	3R152-P100J	Fixed composition: 100 ohms ±5%, 1/4 w.
R13 R14*	3R77-P224K 19B209358-P106	Fixed composition: 0.22 megohm ±10%, 1/2 w.
	19B201969-P6	Variable carbon film: approx 75-10,000 ohms ±20%, 0.25 w. In Models 4ET55A12, 15, 17 and 18 REV. C and earlier; in Models 4ET55A10, 11, 13, 14 and 16 REV. D and earlier; in Models 4ET55A21, 24, 26 and 27 REV. E and earlier; and in Models 4ET55A19, 20, 22, 23, and25 REV. F and earlier: Variable, carbon film: .01 megohm ±20%, 0.1 w, linear taper; sim to Centralab Series 4.
R15 and R16	3R77-P224K	Fixed composition: 0.22 megohm ±10%, 1/2 w.
R17	3R77-P473K	Fixed composition: 47,000 ohms $\pm 10\%$, $1/2$ w.
R18	3R77-P623K	Fixed composition: $62,000$ ohms $\pm 10\%$, $1/2$ w.
	3R77-P103K	Fixed composition: $10,000$ ohms $\pm 10\%$, $1/2$ w.
R19		Variable carbon film: approx 75-25,000 ohms
R19 R20*	19B209358-P107	±20%, 0.25 w. In Models 4ET55A21, 24, 26 and
	19B209358-P107 19B201969-P7 19B201969-P6	±20%, 0.25 w. In Models 4ET55A21, 24, 26 and 27 REV. D & E; and in Models 4ET55A19, 20, 22, 23 and 25 REV. D, E & F; avariable carbon film: 25,000 ohms ±20%, 1/2 w. (Used in Models 4ET55A19-27). In Models earlier than REV. C: Variable; carbon film: .01 megohm ±20%, 0.1 w,

MBOL	G-E PART NO	DESCRIPTION									
		SUBASSEMBLIES(Cont'd)	SYMBOL	G-E PART NO	DESCRIPTION	SYMBOL	G-E PART NO	DESCRIPTION	SYMBOL	G-E PART NO	DESCRIPTION
		INDUCTORS(Cont'd)			SUBASSEMBLIES(Cont'd)			SUBASSEMBLIES(Cont'd)			SUBASSEMBLIES(Cont'd)
L3A	PL-19B204649-G1	Coil, (Used in Models 4ET55Al0, 13, 16, 19,			RESISTORS(Cont'd)			THERMISTORS(Cont'd)			
	5491798- P4	22, 25, 28, 31 and 34). Includes: Tuning slug.	R22	3R77-P153K	Fixed composition: 15,000 ohms ±10%, 1/2 w.	RT2A	19B209284-P3	Rod: 135,000 ohms res nominal at 25°C, color code orange. (Used in Models 4ET55Al0, 11,	Y2	19B206175-P2	Quartz: freq range 2750 to 3500 KC, temp range -30°C to +85°C. (33-42 MC).
			R23	3R77-P682J	Fixed composition: 6800 ohms $\pm 5\%$, $1/2$ w. (Used in Models $4\text{ET55Al3}{-}18$, $22{-}27$, $31{-}36$).			13, 14, 16, 17, 19, 20, 22, 23, 25, 26, 28, 29, 31, 32, 34 and 35).	Y2	19B206175-P3	(Used in Models 4ET55Al3-18, 22-36). Quartz: freq range 3500 to 4500 KC, temp range -30°C to +85°C. (42-50 MC).
L3B	PL-19B204650-G1	Coil. (Used in Models 4ET55All, 12, 14, 15, 17, 18, 20, 21, 23, 24, 26, 27, 29, 30, 32,	R24	3R77-P153K	Fixed composition: 15,000 ohms $\pm 10\%$, $1/2$ w. (Used in Models 4ET55Al3-18, 22-27, 31-36).	RT2B	19B209284-P1	Rod: 100,000 ohms res nominal at 25°C, color code brown. (Used in Models 4ET55Al2, 15, 18, 21, 24, 27, 30, 33 and 36).			range -30°C to +85°C. (42-50 MC). (Used in Models 4ET55Al3-18, 22-36).
		33, 35 and 36). Includes:	R25	3R77-P682J	Fixed composition: 6800 ohms $\pm 5\%$, $1/2$ w. (Used in Models $4\text{ET}55\text{Al}6-18$, $25-27$, $34-36$).	RT3A	19B209284-P10	Disc: 256 ohms res nominal at 25°C, color	Y3 and Y4	19B206175-P1	Quartz: freq range 2083 to 2750 KC, temp range -30°C to +85°C. (25-33 MC). (Used in Models 4ET55A16-18, 25-27, 34-36).
	5491798-P4	Tuning slug.	R26	3R77-P153K	Fixed composition: $15,000 \text{ ohms } \pm 10\%$, $1/2 \text{ w.}$ (Used in Models 4ET55A16-18, 25-27, 34-36).			code brown/black. (Used in Models 4ET55Al3, 14, 16, 17, 22, 23, 25, 26, 31, 32, 34 and 35).	ү з	19B206175-P2	Quartz: freq range 2750 to 3500 KC, temp range -30°C to +85°C. (33-42 MC).
			R27	3R77-P682J	Fixed composition: 6800 ohms ±5%, 1/2 w. (Used in Models 4ET55A16-18, 25-27, 34-36).	RT3B	19B209284-P9	Disc: 100 ohms res nominal at 25°C, color code white. (Used in Models 4ET55Al5, 18,	and Y4		(Used in Models 4ET55A16-18, 25-27, 34-36).
L4A	PL-19B204649-G2	Coil. (Used in Models 4ET55AlO, 13, 16, 19, 22, 25, 28, 31 and 34). Includes:	R28	3R77-P153K	Fixed composition: 15,000 ohms ±10%, 1/2 w. (Used in Models 4ET55A16-18, 25-27, 34-36).	RT4A	19B209284-P3	24, 27, 33 and 36). Rod: 135,000 ohms res nominal at 25°C, color	Y3 and Y4	19B206175-P3	Quartz: freq range 3500 to 4500 KC, temp range -30°C to +85°C. (42-50 MC). (Used in Models 4ET55A16-18, 25-27, 34-36).
	5491798-P4	Tuning slug.	R29	3R77-P153J	Fixed composition: 15,000 ohms ±5%, 1/2 w.	l l	195203264-13	code orange. (Used in Models 4E755Al3, 14, 16, 17, 22, 23, 25, 26, 31, 32, 34 and 35).			(
			R30	3R77-P101K	Fixed composition: 100 ohms $\pm 10\%$, $1/2$ w.	RT4B	19B209284-P1	Rod: 100,000 ohms res nominal at 25°C, color code brown. (Used in Models 4ET55A15, 18,			
L4B	PL-19B204650-G3	17, 18, 20, 21, 23, 24, 26, 27, 29, 30, 32, 33, 35 and 36). Includes:	R31A	3R77-P272J	Fixed composition: 2700 ohms ±5%, 1/2 w. (Used in Models 4ET55A10, 11, 13, 14, 16, 17, 19, 20, 22, 23, 25, 26, 28, 29, 31, 32, 34 and 35).	RT5A	19B209284-P10	24, 27, 33 and 36). Disc: 256 ohms res nominal at 25°C, color code brown/black. (Used in Models 4ET55A16,			BOARD ASSEMBLY PL-19B204927-G1 (Used in PL-19D402385 G1-3, 6-8, 11-13, 16-18, 21-23, 26-28)
	5491798- P 4	Tuning slug.	R31B	3R77-P202J	Fixed composition: 2000 ohms ±5%, 1/2 w. (Used in Models 4ET55A12, 15, 18, 21, 24, 27, 30, 33 and 36).	RT5B	19B209284-P9	17, 25, 26, 34 and 35). Disc: 100 ohms res nominal at 25°C, color code white. (Used in Models 4ET55Al8, 27			JACKS AND RECEPTACLES
		TRANSISTORS	R33A	3R77-P393K	Fixed composition: 39,000 ohms ±10%, 1/2 w. (Used in Models 4ET55AlO and 13).	RT6A	19B209284-P3	and 36). Rod: 135,000 ohms res nominal at 25°C, color code orange. (Used in Models 4E755Al6, 17.	J1 thru J10	4033513-P4	Contact, electrical: sim to Bead Chain L93-3.
Q1 and Q2	19A115123-P1	Silicon, NPN; sim to Type 2N2712.	R33B	3R77-P273K	Fixed composition: $27,000$ ohms $\pm 10\%$, $1/2$ w. (Used in Models 4ET55All, 14 and 17).	naman.	10000001 01	25, 26, 34 and 35).	J12 thru J17	4033513-P4	Contact, electrical: sim to Bead Chain L93-3.
Q3 and Q4	19A115330-P1	Silicon, NPN.	RЗЗС	3R77-P223K	Fixed composition: 22,000 ohms $\pm 10\%$, 1/2 w. (Used in Models 4ET55A12, 15 and 18).	RT6B	19B209284-P1	Rod: 100,000 ohms res nominal at 25°C, color code brown. (Used in Models 4ET55Al8, 27 and 36).			
Q4 Q5	19A115328-P1	Silicon, NPN.	R34A	3R77-P223K	Fixed composition: 22,000 ohms $\pm 10\%$, 1/2 w. (Used in Models 4ET55A19, 22, 25, 28, 31 and 34).	RT7A	19B209284-P10	Disc: 256 ohms res nominal at 25°C, color code brown/ black. (Used in Models 4ET55Al6, 17, 25, 26, 34 and 35).	Al45 thru		POWER AMPLIFIER BOARD ASSEMBLY
Q6*	19A115328-P1	Silicon: NPN. In Models 4ET55Al2, 15, 17 and 18 REV. C and earlier; in Models 4ET55Al0, 11, 13, 14 and 16 REV. D and earlier; in Models	R34B	3R77-P153K	Fixed composition: 15,000 ohms ±10%, 1/2 w. (Used in Models 4ET55A20, 23, 26, 29, 32 and 35).	RT7B	19B209284-P9	Disc: 100 ohms res nominal at 25°C, color code white. (Used in Models 4ET55Al8, 27 and 36).	Al47		A145 (19C303542-G6) (4ET55A10, 13, 16, 19, 22, 25, 28, 31 and 34) A146 (19C303542-G7) (4ET55A11, 14, 17, 20,
	19A115329-P1	4ET55A21, 24, 26 and 27 REV. E and earlier; and in Models 4ET55A19, 20, 22, 23 and 25 REV. F and earlier: Silicon: NPN.	R34C	3R77-P103K	Fixed composition: 10,000 ohms ±10%, 1/2 w. (Used in Models 4ET55A21, 24, 27, 30, 33 and 36).	RT8A	19B209284-P3	Rod: 135,000 ohms res nominal at 25°C, color code orange. (Used in Models 4E755Al6, 17, 25, 26, 34 and 35).			23, 26, 29, 32 and 35) A147 (19C303542-G8) (4ET55A12, 15, 18, 21, 24, 27, 30, 33 and 36)
Rl	3R77-P334K	Fixed compositions 0.22 months 100 1/2 m	R35A	3R77-P473K	Fixed composition: 47,000 ohms ±10%, 1/2 w. (Used in Models 4ET55A19, 20, 22, 23, 25,	RT8B	19B209284-P1	Rod: 100,000 ohms res nominal at 25°C, color code brown. (Used in Models 4ET55Al8, 27	C1	5494481-Pl12	CAPACITORS
R2	3R77-P105K	Fixed composition: 0.33 megohm ±10%, 1/2 w. Fixed composition: 1 megohm ±10%, 1/2 w.	R35B	3R77-P333K	26, 28, 29, 31, 32, 34 and 35). Fixed composition: 33,000 ohms ±10%, 1/2 w.			and 36).	thru C3	0454401-F112	500 VDCW; sim to RMC Type JF Discap.
R3*	3R77-P472K	Fixed composition: 4700 ohms ±10%, 1/2 w. In Models 4FT55All, 12, 14, 15, 17 and 18			(Used in Models 4ET55A21, 24, 27, 30, 33 and 36).				C4	5496219-P869	Ceramic disc: temp-comp, radial leads, 180 pf ±5%, 500 VDCW, temp coef -1500 PPM.
		REV. B and earlier; in Models 4ET55A10, 13 and 16 REV. C and earlier; in Models 4ET55A20, 21, 23, 24, 26 and 27 REV. D and earlier; and	R36	3R77-P103K	Fixed composition: 10,000 ohms $\pm 10\%$, 1/2 w.	т1*	PL-19B204651-G1	(Used in Models 4ET55A19-27, REV. A and earlier).	C5 and	5494481-P112	Ceramic disc: radial leads, .001 µf ±10%, 500 VDCW; sim to RMC Type JF Discap.
	3R77-P682K	in Models 4ET55Al9, 22 and 25 REV. E and earlier: Fixed composition: 6800 ohms ±10%, 1/2 w.	R37	3R77-P103K	Fixed composition: 10,000 ohms $\pm 10\%$, $1/2$ w. (Used in Models 4ET55A19-36).	T2*	19B205262-G1	(Used in Models 4ET55A10-18 earlier than REV. A).	C6	5496219~ P 875	Ceramic disc: temp-comp, radial leads,
R4	3R77-P274K	Fixed composition: 0.27 megohm ±10%, 1/2 w.	R38	3R77-P683K	Fixed composition: 68,000 ohms ±10%, 1/2 w.			(Added by REV. A to Models 4ET55A10-18). (Added by REV. B to Models 4ET55A19-27).			330 pf ±5%, 500 VDCW, temp coef -1500 PPM.
R5 R6	3R77-P224K 3R77-P683K	Fixed composition: 0.22 megohm ±10%, 1/2 w. Fixed composition: 68,000 ohms ±10%, 1/2 w.	R39 R41	3R77-P392K 3R77-P750J	Fixed composition: 3900 ohms ±10%, 1/2 w. Fixed composition: 75 ohms ±5%, 1/2 w.				C8	5494481-P112	Ceramic disc: radial leads, .001 µf ±10%, 500 VDCW; sim to RMC Type JF Discap.
R7	3R77-P334K	Fixed composition: 0.33 megohm ±10%, 1/2 w.	R42	3R77-P391J	Fixed composition: 390 ohms ±5%, 1/2 w.			SOCKETS	C9	5496219-P241	Ceramic disc: temp-comp, radial leads, 10 pf ±5%, 500 VDCW, temp coef -80 PPM.
R8	3R77-P684K	Fixed composition: 0.68 megohm ±10%, 1/2 w.	R43	3R77-P360J	Fixed composition: 36 ohms ±5%, 1/2 w.	XY1	1	Refer to Mechanical Parts (RC-1198).			(Used in Models 4ET55A10, 13, 16, 19, 22, 25, 28, 31 and 34).
R9	3R77-P334K	Fixed composition: 0.33 megohm ±10%, 1/2 w.	R44	3R77-P121J	Fixed composition: 120 ohms $\pm 5\%$, $1/2$ w.	XY2		Refer to Mechanical Parts (RC-1198). (Used in Models 4ET55Al3-18, 22-27, 31-36).	C10	5496219-P239	Ceramic disc: temp-comp, radial leads,
R10	3R77-P683K	Fixed composition: 68,000 ohms ±10%, 1/2 w.	R45	5495948-P474	Deposited carbon, epoxy coated: 0.576 megohm ±1%, 1/2 w; sim to Texas Instruments Type	хүз		Refer to Mechanical Parts (RC-1198).	li .		8 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM. (Used in Models 4ET55All, 14, 17, 20, 23, 26, 29, 32 and 35).
R11 R12*	3R77-P122K 3R152-P100J	Fixed composition: 1200 ohms ±10%, 1/2 w. Fixed composition: 100 ohms ±5%, 1/4 w.	R46	anga Ploor	CD1/2MR.	and XY4		(Used in Models 4ET55A16-18, 25-27, 34-36).	C11	5496219~P236	Ceramic disc: temp-comp, radial leads.
R13	3R77-P224K	Fixed composition: 0.22 megohm ±10%, 1/2 w.	R45	3R77-P100K 3R77-P330J	Fixed composition: 10 ohms ±10%, 1/2 w. Fixed composition: 33 ohms ±5%, 1/2 w.						5 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM. (Used in Models 4ET55Al2, 15, 18, 21, 24, 27, 30, 33 and 36).
R14*	19B209358-P106	Variable carbon film: approx 75-10,000 ohms ±20%, 0.25 w. In Models 4ET55A12, 15, 17	R48	3R77-P222K	Fixed composition: 2200 ohms ±10%, 1/2 w.			When reordering give G-E Part No. and specify	Cl3	5496219-P251	Ceramic disc: temp-comp, radial leads,
		and 18 REV. C and earlier; in Models 4ET55A10, 11, 13, 14 and 16 REV. D and earlier; in Models	R49	3R77-P101K	Fixed composition: 100 ohms ±10%, 1/2 w.			exact freq needed. Crystal Freq = (OF + 12).		0.00020 1201	33 pf ±5%, 500 VDCW, temp coef -80 PPM. (Used in Models 4ET55AlO, 11, 13, 14,
		4ET55A21, 24, 26 and 27 REV. E and earlier; and in Models 4ET55A19, 20, 22, 23, and25 REV. F and earlier;				Yl	19B206175-P1	Quartz: freq range 2083 to 2750 KC, temp range -30°C to +85°C. (25-33 MC).			16, 17, 19, 20, 22, 23, 25, 26, 28, 29, 31, 32, 34 and 35).
	19B201969~P6	Variable, carbon film: .01 megohm ±20%, 0.1 w, linear taper; sim to Centralab Series 4.	RT1A	19B209284-P10	Disc: 256 ohms res nominal at 25°C, color	Yı	19B206175-P2	Quartz: freq range 2750 to 3500 KC, temp	C15	5496219-P242	Ceramic disc: temp-comp, radial leads, 12 pf ±5%, 500 VDCW, temp coef -80 PPM. (Used in Models 4ET55Al2, 15, 18, 21,
R15 and	3R77-P224K	Fixed composition: 0.22 megohm ±10%, 1/2 w.			code brown/black. (Used in Models 4ET55Al0, 11, 13, 14, 16, 17, 19, 20, 22, 23, 25, 26, 28, 29, 31, 32, 34 and 35).	Y1	19B206175-P3	range -30°C to +85°C. (33-42 MC). Quartz: freq range 3500 to 4500 KC, temp			(Used in models 4E155A12, 15, 18, 21, 24, 27, 30, 33 and 36).
R16			RT1B	19B209284-P9	Disc: 100 ohms res nominal at 25°C, color			range -30°C to +85°C, (42-50 MC).	ll		
R17	3R77-P473K 3R77-P623K	Fixed composition: 47,000 ohms ±10%, 1/2 w.			code white. (Used in Models 4ET55Al2, 15; 18, 21, 24, 27, 30, 33 and 36).	Y2	19B206175-P1	Quartz: freq range 2083 to 2750 KC, temp range -30°C to +85°C. (25-33 MC). (Used in Models 4ET55Al3-18, 22-36).	[]		
R18 R19	3R77-P623K 3R77-P103K	Fixed composition: 62,000 ohms ±10%, 1/2 w. Fixed composition: 10,000 ohms ±10%, 1/2 w.						Cool II Boucis ibiodalo-10, 44-30).			
R20*	19B209358-P107	Variable carbon film: approx 75-25,000 ohms									
		±20%, 0.25 w. In Models 4ET55A21, 24, 26 and 27 REV. D & E; and in Models 4ET55A19, 20, 22, 23 and 25 REV. D, E & F:									
	19B201969-P7	Variable carbon film: 25,000 ohms ±20%, 1/2 w. (Used in Models 4ET55A19-27). In Models earlier than REV. C;							. ———	-	(CONT'D ON PAGE 13)
	19B201969-P6	Variable; carbon film: .01 megohm ±20%, 0.1 w, linear taper: sim to Centralab Series 4.									

(CONT'D FROM PA	GE 12) (LBI-3531)
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SYMBOL	G-E PART NO	DESCRIPTION	SYMBOL	G-E PART NO	DESCRIPTION
		SUBASSEMBLIES(Cont'd)			SUBASSEMBLIES(Cont'd)
				1	= = = RESISTORS(Cont'd) =
			R20	3R79-P473J	Fixed composition: 47,000 ohms ±5%, 2 w.
			R21	3R79-P432J	Fixed composition: 4300 ohms ±5%, 2 w.
L1	PL-19B205051-G1	Coil. (Used in Models 4ET55AlO, 13, 16,	and R22		
		19, 22, 25, 28, 31 and 34). Includes:	R23	3R79-P473J	Fixed composition: 47,000 ohms ±5%, 2 w.
	7142014-P16 7127634-P2	Tuning slug. Speed clip.	R24*	3R79-P333J	Fixed composition: 33000 ohms ±5%, 1 w. (Used in Models 4ET55All, 12, 14, 15, 17, 18, 20, 21, 23, 24, 26 and 27).
	ľ				
L2	PL-19B205051-G2	Coil. (Used in Models 4ET55All. 12. 14.	V1	}	Type 8106.
		Coil. (Used in Models 4ET55All, 12, 14, 15, 17, 18, 20, 21, 23, 24, 26, 27, 29, 30, 32, 33, 35 and 36). Includes:			
	7142014-P16	Tuning slug.	Wl	PL-19A121361-G1	Cable, RF: includes 2 contacts, approx 11 inches long.
	7127634-P2	Speed clip.			II Inches long.
					SOCKETS
			XV1	7489470-P2	Tube, mica-filled phen: 8 pins rated at 1 amp.
L6	PL-19B205051-G6	Coil. (Used in Models 4ET55AlO, 13, 16, 19, 22, 25, 28, 31 and 34). Includes:			
	7142014-P16	Tuning slug.			
	7127634-P2	Speed clip.			BOARD ASSEMBLY PL-19B204931-G1 (Used in PL-19C303542 G6-8)
L7	PL-19B205051-G7	Coil. (Used in Models 4ET55All, 12, 14, 15, 17, 18, 20, 21, 23, 24, 26, 27, 29, 30, 32, 33, 35 and 36). Includes:	J1	4033513-P4	Contact, electrical: sim to Bead Chain L93-3.
		30, 32, 33, 35 and 36). Includes:	thru J9		
	7142014-P16	Tuning slug.			
	7127634-P2	Speed clip.			
L9	PL-19B204614-G1	Coil (Used in Models 4FT55410 13 16	C105 and	5494481-P12	Ceramic disc: radial leads, .001 μ f \pm 10%, 500 VDCW; sim to RMC Type JF Discap.
19	FL-19B204014-Q1	Coil. (Used in Models 4ET55AlO, 13, 16, 12, 22, 25, 28, 31 and 34). Includes:	C106		a at .1turk a food them. and 1 loads
	5491798-P4	Tuning slug.	C107	7485975-P17	Ceramic dielectric, feed-thru: axial leads, 470 pf ±20%, 750 VDCW; sim to Erie Style 327.
		0.13 (T. 1.1. 1.1. 1.1. 1.1. 1.1. 1.1. 1.1.	C109	7478981-P2	Silver mica: temp-comp, axial leads, 470 pf $\pm 10\%$, 1500 VDCW, temp coef ± 500 PPM. Type RCM20B.
L10	PL-19B204614-G2	Coil. (Used in Models 4ET55All, 14, 17, 20, 23, 26, 29, 32 and 35). Includes:	C110	5491498-P3	Variable, air dielectric: approx 2.8-50 pf, 1700 v peak. (Used in Models
	5491798-P4	Tuning slug.			4ET55A12, 15, 18, 21, 24, 27, 30, 33 and 36).
			C111	19B209123~P1	Variable, air dielectric: approx 6.5-50 pf; sim to Hammarlund Type APC.
			C112	5491498- P 4	Variable, air dielectric: approx
L11	PL-19B204614-G3 5491798-P4	Coil. (Used in Models 4ET55Al2, 15, 18, 21, 24, 27, 30, 33 and 36). Includes: Tuning slug.		0451450-24	5.8-75 pf, 1700 v peak. (Used in Models 4ET55Al0, 11, 13, 14, 16, 17, 19, 20, 22, 23, 25, 26, 28, 29, 31, 32, 34 and 35).
			Cll7 and	5494481-P12	Ceramic disc: radial leads, .001 µf ±10%, 500 VDCW; sim to RMC Type JF Discap.
			C118	#4001.22 ===	,
			C119	7489162-P39	Silver mica, dipped phen: radial leads, 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
R1	3R77-P153J	Fixed composition: 15,000 ohms ±5%, 1/2 w.	C122	5492304~P8	
R2 R3	3R77-P221J 3R77-P473J	Fixed composition: 220 ohms ±5%, 1/2 w. Fixed composition: 47,000 ohms ±5%, 1/2 w.		340004-20	Ceramic disc: temp-comp, radial leads, 3 pf ±0.25 pf, 2000 VDCW, temp coef -0 ±120 PPM.
R6*	3R79-P473J	Fixed composition: 47,000 ohms 15%, 2 w. (Used in Models 4ET55Al0, 13, 16, 19, 22 and 25).	C124 and C125	5494481-P12	Ceramic disc: radial leads, .001 μf $\pm 10\%,\ 500$ VDCW; sim to RMC Type JF Discap.
R7	3R77-P221K 3R78-P432J	Fixed composition: 220 ohms ±10%, 1/2 w. Fixed composition: 4300 ohms ±5%, 1 w.	FL1		Reed, governor: coil - 600 ohms ±10%,
RS R11	3R78-P432J 3R77-P680J	Fixed composition: 4300 onms 15%, 1 w. Fixed composition: 68 ohms ±5%, 1/2 w.			standard 7-pin tube socket mounting. (Used in Models 4ET55Al9-36).
RII RI5	5495948-P444	Deposited carbon, epoxy coated: 0.28 megohm		3R161-P719	71.9 cps
		$\pm 1\%$, $1/2$ w; sim to Texas Instruments Type CD1/2MR.		3R161-P770 3R161-P825	77.0 cps 82.5 cps
R17	3R78-P683K	Fixed composition: 68,000 ohms ±10%, 1 w.		3R161-P885 3R161-P948 3R161-P1000	88.5 cps 94.8 cps 100.0 cps
R18	3R79-P432J	Fixed composition: 4300 ohms ±5%, 2 w.		3R161-P1000 3R161-P1035 3R161-P1072	103.5 cps 107.2 cps
and R19					
					(CONT'D ON PAGE 14)

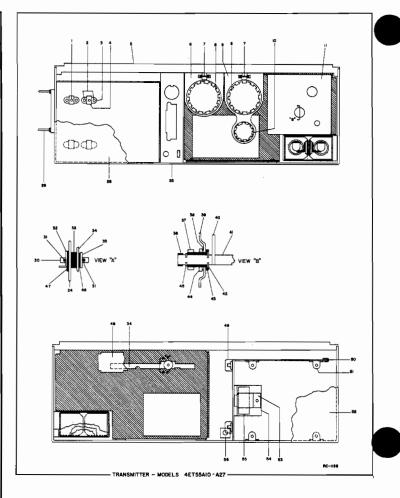
	M PAGE 13) (LBI-:	3531)			
YMBOL	G-E PART NO	DESCRIPTION	SYMBOL	G-E PART NO	DESCRIPTION
	3R161-P1109 3R161-P1148 3R161-P1148 3R161-P1230 3R161-P1273 3R161-P1318 3R161-P1412 3R161-P1412 3R161-P1514 3R161-P1514 3R161-P1514 3R161-P1679 3R161-P1779 3R161-P1799 3R161-P1799	110.9 cps 114.8 cps 114.8 cps 123.0 cps 127.3 cps 131.8 cps 131.5 cps 141.3 cps 141.3 cps 146.2 cps 151.4 cps 156.7 cps 162.2 cps 173.8 cps 173.8 cps 162.2 cps 179.9 cps 179.9 cps 179.9 cps 186.2 cps	K1 Q1 thru Q4	5494796~P6 19A115123~P1	Armature, open: 12 VDC nominal, 2 w max operating, 96 ohms ±15% coil res, 2 form A and 2 form C contacts rated at 2 amps at 115 VAC or 28 VDC; sim to Potter Brumfield Type MG. (Used in Models 4ET55A28-36).
	3R161-P2035	192.8 cps 203.5 cps LOW PASS FILTER ASSEMBLY The low pass filters are factory tuned. If a filter component is found to be defective, it is	R1 R2 R3	3R77-P562K 3R77-P201K 3R77-P682J 3R77-P512K	Fixed composition: 5600 ohms ±10%, 1/2 w. Fixed composition: 200 ohms ±10%, 1/2 w. Fixed composition: 6800 ohms ±5%, 1/2 w. Fixed composition: 5100 ohms ±10%, 1/2 w.
FL101	19D402233-G1	recommended that the entire filter assembly be replaced to maintain rated power output and spurious attenuation. 25-33 MC (Used on Models 4ET55A10, 13, 16, 19,	R5	3R77-P912K 3R77-P123K	In Models 4ET55A19-27 earlier than REV. A: Fixed composition: 9100 ohms ±10%, 1/2 w. Fixed composition: 12,000 ohms ±10%, 1/2 w.
FL102	19D402233-G2	22, 25).	R6	3R77-P512K	Fixed composition: 5100 ohms ±10%, 1/2 w.
		33-42 MC (Used on Models 4ET55All, 14, 17, 20, 23, 26).	R7 R8	3R77-P132K 3R77-P622K	Fixed composition: 1300 ohms ±10%, 1/2 w. Fixed composition: 6200 ohms ±10%, 1/2 w.
FL103	19D402233-G3	42-50 MC (Used on Models 4ET55Al2, 15, 18, 21, 24, 27).	R9	3R77-P122K	Fixed composition: 1200 ohms ±10%, 1/2 w.
			RlO	3R77-P302J	Fixed composition: 3000 ohms $\pm 5\%$, $1/2$ w.
		OSCILLATORS	R11 R12	3R77-P273J 7491365-P220	Fixed composition: 27,000 chms ±5%, 1/2 w. Variable, carbon film: .01 megohm ±10%, .08 w, non-linear taper; sim to CTS Type UPE-70.
G101 and		TONE OSCILLATOR ENCODER ASSEMBLY	R13	3R77-P274K	Fixed composition: 0.27 megohm $\pm 10\%$, $1/2$ w.
G102		Gl01 (19C303466-G2) (4ET55A19-27)	R14	3R77-P822K	Fixed composition: 8200 ohms ±10%, 1/2 w.
			R15	3R77-P620K	Fixed composition: 62 ohms $\pm 10\%$, $1/2$ w.
Cl	19B209243-P6	Polyester dielectric: radial leads, .068 µf	R16	3R77-P243K	Fixed composition: 24,000 ohms ±10%, 1/2 w.
	100200110 70	±20%, 40 VDCW; sim to Amperex C280AA/P68K.	R17	3R77-P153K	Fixed composition: 15,000 ohms ±10%, 1/2 w.
C2	7489483-P17	Tubular, hermetically sealed, electrolytic: axial leads, 50 µf +75% -10%, 25 VDCW; sim	R18	3R77-P102K 3R77-P184K	Fixed composition: 1000 ohms ±10%, 1/2 w. Fixed composition: 0.18 megohm ±10%, 1/2 w.
СЗ	19A115414-P216	to Sprague 30D186Al. Tubular, Mylar⊗ dielectric: radial leads,	R20	3R77-P622J	Fixed composition: 6200 ohms ±5%, 1/2 w.
		0.33 µf ±5%, 100 VDCW.	R21	3R77-P330K	Fixed composition: 33 ohms ±10%, 1/2 w.
C4	19B209243-P2	Polyester dielectric: radial leads, .015 µf ±20%, 40 VDCW; sim to Amperex C280AA/P15K.	R22	3R77-P183K	Fixed composition: $18,000$ ohms $\pm 10\%$, $1/2$ w.
C5	19B209243-P9	Polyester dielectric: radial leads, 0.22 µf	R23	3R77-P623K	Fixed composition: $62,000$ ohms $\pm 10\%$, $1/2$ w.
C6	19B209243-P8	±20%, 40 VDCW; sim to Amperex C280AA/P220K. Polyester dielectric: radial leads, 0.15 µf	R24	3R77-P333J	Fixed composition: 33,000 ohms ±5%, 1/2 w.
		±20%, 40 VDCW; sim to Amperex C280AA/P150K.	R25	3R77-P393K	Fixed composition: 39,000 ohms ±10%, 1/2 w.
C7 C8	19B209243-P3 19A115414-P17	Polyester dielectric: radial leads, .022 µf ±20%, 40 VDCW; sim to Amperex C280AA/P22X. Tubular, Mylar® dielectric: radial leads 0.47 µf ±20%, 100 VDCW.	RTI	5490828-P30	Rod: radial leads, 0.33 megohm ±10% res, lw max; sim to Globar Type 783H-3.
C9	19B209243-P9	Polyester dielectric: radial leads, 0.^2 µf ±20%, 40 VDCW; sim to Amperex C280AA/P220K.			
C10	19All5414-P216	Tubular, Mylar® dielectric: radial leads, 0.33 µf ±5%, 100 VDCW.	XFL1	PL-19A121920-G1	Reed, mica-filled phen: 7 pins rated at 1 amp at 500 VRMS with 4-1/2 inches of cable.
C11 and C12	5494481-P107	Ceramic disc: radial leads, 470 pf ±20%, 500 VDCW; sim to RMC Type JF Discap.			
C13	19B209243-P8 5494481-P111	Polyester dielectric: radial leads, 0.15 µf ±20%, 40 VDCW; sim to Amperex C280AA/P150K. (Used in Models 4ET55A28-36). Ceramic disc: radial leads, .001 uf ±20%,			BOARD ASSEMBLY PL-19B204542-Gl (4ET55A28-36) PL-19B204542-G2 (4ET55A19-27)
CR1* thru CR3*	19A115250-P1 4036936-P1	Silicon. Legan College Fadiat leags, John H 120%, 500 VDCW; sim to RMC JF Discap. Added in Models 4ET55A19-27 by REV. A. DIODES AND RECTIFIERS Silicon. In Models 4ET55A19-27 earlier than REV. A: Silicon.	J1 thru J8	4033513-P4	

(CONT'D ON PAGE 1

	G-E PART NO	DESCRIPTION	SYMBOL	G-E PART NO	DESCRIPTION
J101	PL-19C303426-G1	JACKS AND RECEPTACLES Connector: 20 pin contacts.	Y101 and	_	TUBES
J102	19B209125-P1	Connector, Lexano: 18 contacts rated at 5 amps min at 1000 VDC max.	V102		
L101	7772834-P4	Choke, RF: 7 μh, approx freq range 35 to 110 mc; sim to Ohmite 7-50.	XV101 and XV102	19C3O1OO7-P5	Tube, plastic: 12 pins rated at 5 amps max; sim to Alcon Metal Products 371G bottom mount
L110	19A121378-P1	Coil. (Used in Models 4ET55Al0, 13, 16, 19, 22, 25, 28, 31 and 34).			
L111	19A121379~P2	Coil. (Used in Models 4ET55All, 14, 17, 20, 23, 26, 29, 32 and 35).			MECHANICAL PARTS
L112	19A121379-P1	Coil. (Used in Models 4ET55Al2, 15, 18, 21, 24, 27, 30, 33 and 36).			(SEE RC-1198)
L115	19A121377-P2	Coil. (Used in Models 4ET55Al0, 13, 16, 19, 22, 25, 28, 31 and 34).	1	19B200525-P8	Rivet. (Part of XY1-4).
L116	19A121376-P2	Coil. (Used in Models 4ET55All, 14, 17, 20, 23, 26, 29, 32 and 35).	2	4033751-P1	Contact, electrical: sim to Methode 752 V(PB). (Part of XY1-4).
L117	19A121375P1	Coil. (Used in Models 4ET55Al2, 15, 18, 21, 24, 27, 30, 33 and 36).	3 4	4039307-P1 4033089-P1	Crystal socket. (Part of XY1-4). Clip. (Part of XY1-4).
L118*	19A115700-P2	RF Choke. (Used in Models 4ET55A10, 13, 16, 19, 22 and 25).	5	PL-19C3O3395-G2	Heat sink: approx 14-1/2 x 3-1/4 x 1/2 inches thick,
P101	4029840-P2	Contact, electrical: solder coated brass; sim to Amp 42827-2.	6	19B204571-P1	Tube heat sink. (Used with V102).
P102	4029840-Pl	Contact, electrical: solder coated brass; sim to Amp 41854.	7	19A121195-P2	Support: approx $2 \times 5/8 \times 1/16$ inches thick. (Used with V101 and V102).
P103 thru P106	4029840-P2	Contact, electrical: solder coated brass; sim to Amp 42827-2.	8	7165167 - P7	Tube shield insert: approx 5-3/16 x 1-7/8 inches flat; sim to Atlas 106-332-18. (Used with V101 and V102).
P107	4029840- P 1	Contact, electrical: solder coated brass; sim to Amp 41854. (Used in Models 4ET55A19-36).	10	19B204702-P1 7165167-P5	Tube heat sink. (Used with V1). Tube shield insert: approx 2-7/8 x 1-1/4 inches flat; sim to Atlas
P108	4029840-P2	Contact, electrical: solder coated brass; sim to Amp 42827-2. (Used in Models 4ET55A19-36).	11	PL-19B204490-G1	106-332-5. (Used with V1). Can: approx 2 x 3-1/16 x 3-1/4 inches.
P109 and	4029840-P2	Contact, electrical: solder coated brass; sim to Amp 42827-2.	12	PL-19B204565-G1	Casting: approx 1-3/8 x 2-1/2 x 2-7/8 inches. (Includes J1 and J103).
P110 P112	4029840~P2	Contact, electrical: solder coated brass;	13	19A121004-P1	Angle: approx $1/2 \times 1/2 \times 9/16$ inches. (Part of C17-25).
thru P117	4025040	sim to Amp 42827-2.	14	19A121006-P8	Washer: approx 3/4 inches dia. (Part of Cl9).
P120 and P121	4029840-P1	Contact, electrical: solder coated brass; sim to Amp 41854.	15	19A121006-P5	Washer: approx 5/8 inches dia. (Part of C25).
P122 thru	4029840-P2	Contact, electrical: solder coated brass; sim to Amp 42827-2.	16	19A121006-P6	Washer: approx 11/16 inches dia. (Part of C22).
P127	#3.50500 P1		17	19A121018-P3	Washer: approx 7/8 x 1/32 inches dia, Teflon⊕. (Part of C17-25).
P128 P129	7160522-P1 4029840-P2	Plug, phono: phen. Contact, electrical: solder coated brass;	18	4031594-P1	Spacer: approx 1/4 inches dia, Teflon⊕. (Part of C17-25).
P130	4029840-P2	sim to Amp 42827-2. Contact, electrical: solder coated brass;	19	19A121006~P7	Washer: approx 3/4 inches dia. (Part of Cl7 and Cl8).
thru P132		sim to Amp 42827-2. (Used in Models 4ET55A19-36).	20	19A121006~P6	Washer: approx 11/16 inches dia. (Part of C24).
P133	4029840-P1	Contact, electrical: solder coated brass; sim to Amp 41854. (Used in Models 4ET55A19-36).	21	4036835-P4	Solder terminal: sim to Shakeproof 2177-04-000. (Part of C18 and C24).
P134 thru	4029840~P2	Contact, electrical: solder coated brass; sim to Amp 42827-2. (Used in Models	22	19A121006-P3	Washer: approx 5/8 inches dia. (Part of C23).
P137		4ET55A19-36).	23	19A121006-P5	Washer: approx 5/8 inches dia. (Part of C20).
R102	19A115416P2		24	PL-19B204708-G1	Chassis: approx 7-3/4 x 4-1/2 inches.
1,102	15/110410	sim to Dale Type RS-2B.	25	PL-19B204395-G1	Chassis: approx 14-1/2 x 4-3/4 x 3-3/8 inches.
S101	7481654P6		28	PL-19C303396-G1	Cover: approx $14-1/2 \times 4-3/4 \times 5/16$ inches thick.
		Pushbutton: single pole, normally open, 1/2 amp at 115 VAC; sim to Grayhill 30-1.	29	19A121676-P1	Pin guide: 4-40 thread, approx 5/8 inch pin. (Used with J101).
S102	19B209040-P1	Slide: DPDT, 0.5 amp at 125 v; sim to Continental Wirt Type 126.	30 31	19A121465-P1 N509P608C13	Post: approx 7/8 x 3/16 inches dia. Dowel pin, spring: approx 1/2 x
		TERMINAL BOARDS			1/16 inches dia.
TB1	7487424~P2	Miniature, phen: 1 terminal.			

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YMBOL	G-E PART NO	DESCRIPTION
		MECHANICAL PARTS(Cont'd)
32	19B204776-P1	Angle support: approx 5/8 x 1/4 x 1/2 inches wide. (Part of post assembly).
33	19B204756P1	Insulator: approx 1/4 x 1/2 inches dia, ceramic. (Part of post assembly).
34	19C303666-P1	Plate line. (Used with Vl01 and Vl02).
35	N402P39C13	Washer: approx 3/16 inches dia. No. 10.
36	4031527-P2	Collar: approx 1/8 x 5/16 inches.
37	4031531-Pl	Locknut: approx $3/8 \times 4/16$ inches dia. No. 32.
38	7115130 -P 9	Lockwasher: approx 3/8 inches dia; sim to Shakeproof 1220-2.
39	19B205023-P1	Support: approx 1-3/8 x 1/2 x 1/16 inches thick.
40	N509P612C	Dowel pin: approx 3/4 x 1/16 inches dia.
41	19A121189-P2	Post: approx 2-3/8 x 1/4 inches dia.
42	4031532-P1	Cup washer: approx 1/2 inch dia.
43	4031530-P1	Bearing: approx 3/8 x 1/16 inches dia, No. 32.
44	7893936-Pl	Nut: approx $3/8 \times 1/2$ inches dia. No. 32.
45	N910P18C	Retaining ring: approx $1/32 \times 5/16$ inches dia.
46	5493361-P6	Spring washer: approx 1/2 inch dia; sim to Shakeproof 3502-10-79.
47	19A121547-P1	Plate: approx 13/16 x 1/2 x 3/32 inches thick. (Part of post assembly).
48	19B204640-P1	Shield. (Used with V101 and V102 line plate).
49	4036921-P1	Mounting support, bottom cover: approx 7/8 x 5/8 x 1/32 inches dia; sim to Tinnerma C17609-8A-67.
50	4029030-P10	Rubber channel: approx 1-1/4 inches long.
51	19B204366-P1	Support: approx 11/16 x 3/8 x 1/16 inches thick.
52	PL-19C3O3396-G3	Cover: approx 14-3/8 x 4-3/4 x 5-16 inches thick,
53	19A121065-P1	Support: (Used with FL1 in Models 4ET55A20-36).
54	PL-19Al21257-Gl	Angle. (Used with FL1 in Models 4ET55A20~36).
55	4032591-P26	Rubber pad: approx 1-1/2 x 3/4 x 1/8 inches thick, adhesive back.
56	4036835P3	Solder terminal; sim to Shakeproof 2149-14-000. (Used with S101).
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PRODUCTION CHANGES

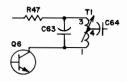
Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter" which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

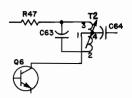
- REV. A Models 4ET55A19-27 only
 To reduce Channel Guard distortion: Changed CR1, CR2, CR3, and R4 and added Cl4 on Channel Guard Board Gl01.
- REV. A Models 4ET55A10-18 only
 REV. B Models 4ET55A19-27 only
 To improve stability of 2nd Multiplier. Changed T1 on Exciter Board A101-A130.

Elementary Diagram Changes:

Was

Changed To





- REV. C Models 4ET55A19-27 only
 To reduce Channel Guard distortion at low tone frequencies. Changed CHANNEL GUARD MOD ADJUST R20 on Exciter Board A101-A130,
- REV. B Models 4ET55A10, 13 & 16 only
 REV. D Models 4ET55A10, 22, 25, 27 only
 To improve tuning and MULT-1 reading. Added C16, C23, C30 and C37 in oscillator section of 25-33 MC Exciter boards.
- REV. C Models 4ET55A10, 13 and 16.
- REV. E Models 4ET55A19, 22 and 25.
 To eliminate RF from high B+ and metering leads in 25-33 MC range. Added L118.
- REV. B Models 4ET55A11, 12, 14, 15,17 and 18.

 REV. D Models 4ET55A20, 21, 23, 24, 26 and 27.

 To increase grid drive over the 33-42 and 42-50 MC range. Deleted R6 and added R24 to Power Amplifier Board Assemblies A146 andA147.

- REV. C Models 4ET55A11, 12, 14, 15, 17 and 18.

 REV. D Models 4ET55A10, 13, and 16.

 REV. E Models 4ET55A10, 21, 23, 24, 26 and 27.

 REV. F Models 4ET55A19, 22, and 25.

 To increase sensitivity of microphone input. Changed C2 and R3.
- REV. D Models 4ET55All and 14.
 REV. F Models 4ET54A20 and 23.
 To improve stability of crystal oscillator stage. Added C75/C76/C77.

- REV. D Models 4ET55A12, 15, 17 and 18.

 REV. E Models 4ET55A10, 11, 13, 14 and 16.

 REV. F Models 4ET55A21, 24, 26 and 27.

 REV. G Models 4ET55A19, 20, 22, 23 and 25.

 To incorporate improved semiconductor components into the Exciter Board Assembly. Changed C3, CR3-CR6, CV1 and CV2, Q6, R14, and R20. Added CV3 CV6 and R12.